



제 33회 한국반도체학술대회

The 33rd Korean Conference on Semiconductors

2026년 1월 27일(화)~30일(금) | 강원도 하이원리조트 그랜드호텔(컨벤션타워)

A Paradigm Shift in Semiconductors for AI Era

2026-01-28(수), 10:00-19:00

(공식발표시간: 17:30-19:00)

ZONE1 (4층, 로비)

[WP] 포스터세션

E. Compound Semiconductors 분과

WP-075	<p>Segmented-PiN 구조를 통한 고효율 4H-SiC UV 포토다이오드 설계</p> <p>김상엽¹, 최수빈², 박가영², 백두산¹, 정승완¹, 석오균²</p> <p>¹부산대학교 전기전자공학과, ²부산대학교 전기전자공학부</p>
WP-076	<p>빠른 스위칭 동작에서의 SBD 내장형 SiC MOSFET의 스위칭 특성 분석</p> <p>강규혁¹, 정승완¹, 백두산¹, 박진우², 류종현³, 석오균²</p> <p>¹부산대학교 전기전자공학과, ²부산대학교 전기전자공학부, ³부산대학교 기계공학부</p>
WP-077	<p>이중 식각을 통한 전계 완화형 6.5 kV SiC PiN 다이오드 종단 구조 설계</p> <p>박수민¹, 김상엽¹, 정준기¹, 양승리², 백두산¹, 정승완¹, 석오균²</p> <p>¹부산대학교 전기전자공학과, ²부산대학교 전기전자공학부</p>
WP-078	<p>채널링 이온주입을 적용한 1.2kV 급 SiC MOSFET 단락 보호 특성 향상에 관한 연구</p> <p>정준기¹, 박수민¹, 백두산¹, 정승완¹, 양승리², 석오균²</p> <p>¹부산대학교 전기전자공학과, ²부산대학교 전기전자공학부</p>
WP-079	<p>High-Performance AlGaN/GaN-on-Si HEMTs with Controlled Trapping Effects by Periodically Carbon-Doped GaN Buffer and in-Situ SiN Passivation</p> <p>Donghan Kim¹, Honghwi Park^{1,2}, Seung-Hyun Kang¹, Youngjin Park¹, Hongsik Park¹, and Jung-Hee Lee^{1,3}</p> <p>¹School of Electronic and Electrical Engineering, Kyungpook National University, ²School of Electronic Engineering, Kumoh National Institute of Technology, ³L&D Co., Ltd.</p>



WP-080	<p>Analysis of Temperature Characteristics and Zero Temperature Coefficients for AlGa_N/Ga_N MIS-HEMT Irradiated by Proton</p> <p>Soo Bean Song¹, Jin Park¹, Won Suk Koh¹, Gang San Yun¹, Kyeong Min Lim¹, Young Jun Yoon², and In Man Kang¹</p> <p>¹School of Electronic and Electrical Engineering, Kyungpook National University, ²Department of Electronics and Mechanical Engineering, Gyeongbuk National University</p>
WP-081	<p>Analysis of Schottky-Like Ohmic Behavior in Al-Rich AlGa_N HEMTs</p> <p>Sakhone Pharkphoumy and Hyun-Seop Kim</p> <p>Department of Electrical Engineering, Kunsan National University</p>
WP-082	<p>Effect of Proton Irradiation on the Electrical Performance of SnO₂ Field-Effect Transistor with ITO Electrodes</p> <p>Huiseung Kim¹, Jeongtae Kim², Seonchang Kim², Suhyeon Park¹, Dawon Lee¹, Jiseop Byeon¹, Jeongin Seo¹, Dong-Seok Kim², and Roy Byung Kyu Chung¹</p> <p>¹Department of Advanced Materials Science and Engineering, Kyungpook National University, ²Korea Multi-purpose Accelerator Complex, KAERI</p>
WP-083	<p>Impact of AlGa_N Channel Thickness on the Mobility and Reliability of Al-Rich AlGa_N Channel HEMTs</p> <p>Shyam Mohan, Joocheol Jeong, Jaejin Heo, Hyogeun Cho, Mingoo Jo, Minyeong Kim, and Okhyun Nam</p> <p>Convergence Center for Advanced Nano Semiconductor, Department of Semiconductor Engineering, Tech University of Korea</p>
WP-084	<p>광 입사 방식에 따른 알파 산화 갈륨 UV-C 광 검출기 성능 비교</p> <p>조영관¹, 김용기¹, 신명훈¹, 박지현², 전대우²</p> <p>¹한국항공대학교 반도체학과 우주시스템융합전공, ²세라믹기술원 디스플레이소재센터</p>
WP-085	<p>InP Double-Heterojunction Bipolar Transistors with Compact Modeling for High-Frequency and THz Application</p> <p>Hyeon-Bhin Jo and Ki-Jin Kim</p> <p>ICT Device and Packaging Center, KETI</p>
WP-086	<p>La₂O₃ 중간층을 통한 In₂O₃ 박막 트랜지스터의 전기적 성능 및 신뢰성 향상</p> <p>박동욱¹, 박영근¹, 김승훈¹, 신건희², 정원목¹, 유찬미², 이동규², 조병진^{1,2}</p> <p>¹한국과학기술원 전기 및 전자공학부, ²한국과학기술원 반도체공학대학원</p>



WP-087	<p>Al-Rich AlGa_N Channel HEMT Structures with Compositionally Graded AlGa_N Contact Layer</p> <p>Hyogeun Cho, Joocheol Jeong, Shyam Mohan, Jaejin Heo, Minyeong Kim, Mingoo Jo, and Okhyun Nam</p> <p>Convergence Center for Advanced Nano Semiconductor, Department of Semiconductor Engineering, Tech University of Korea</p>
WP-088	<p>In-Situ SiN_x Interlayer for Ohmic Contacts in Al-Rich AlGa_N Channel HEMTs</p> <p>Joocheol Jeong, Shyam Mohan, Jaejin Heo, Hyogeun Cho, Mingoo Jo, Minyeong Kim, and Okhyun Nam</p> <p>Convergence Center for Advanced Nano Semiconductor, Department of Nano-Semiconductor, Tech University of Korea</p>
WP-089	<p>Ellipsometric Study on the Temperature-Dependent Optical Properties of β-InSe</p> <p>DooHyeon Lee¹, Yihyun Moon¹, DongMin Kim¹, Tae Jung Kim¹, Long V. Le², Xuan Au Nguyen¹, and Junho Choi¹</p> <p>¹Department of Physics, Kyung Hee University, ²Institute of Materials Science, Vietnam Academy of Science and Technology</p>
WP-090	<p>LPCVD SiO₂ 기반 High-k-Free MIS-HEMT의 DC/AC 특성 평가</p> <p>김대강, 손보성, 김희진, 이성민, 이왕엽, 박시현</p> <p>영남대학교 전자공학과</p>
WP-091	<p>Monolithic GaN CMOS Integration with N/P-Channel FETs</p> <p>Seung-Su Kim and Ho-Young Cha</p> <p>School of Electronic and Electrical Engineering, Hongik University</p>
WP-092	<p>Study on Al/Ni/W Multilayer for Simultaneous Ohmic Contact to n- and p-type 4H-SiC</p> <p>Jun Hyun Byun¹ and Dae Hwan Kang²</p> <p>¹Department of Materials Science & Engineering, POSTECH, ²Department of Semiconductor Engineering, POSTECH</p>
WP-093	<p>Scaling Behavior of On-State Characteristics in Power GaN HEMTs</p> <p>Ji-Seung Seo, Jin-Sup Kim, and Hyeon-Bhin Jo</p> <p>KETI</p>



WP-094	<p>Characterization of Surface Stability in Cap-Recessed InP HEMTs Grown by MOCVD</p> <p>Geunuk Han, Yunji Jeong, Inseon Song, Kyutae Kim, Keunman Song, Jaephil Shim, and Hyunchul Jang</p> <p>KANC</p>
WP-095	<p>Design Optimization and Electrical Characterization of a Two-Step Ion Implanted Non-Box JFET Doping Profile in 1.2-kV SiC MOSFETs</p> <p>Hee-Jin Kim and Ho-Jun Lee</p> <p>Department of Electrical and Electronics Engineering, Pusan National University</p>
WP-096	<p>Integration of an Active Miller-Clamp and Inverter-Assisted Driver for Reduced Switching Loss in GaN HEMTs</p> <p>Dong-Ho Seo and Ho-Young Cha</p> <p>School of Electronic and Electrical Engineering, Hongik University</p>
WP-097	<p>A Study on the Dependence of Device Dimension on Quasi-Vertical GaN Schottky Barrier Diodes</p> <p>Seongmin Kang, Jinseop Kim, and Hyeon-Bhin Jo</p> <p>KETI</p>
WP-098	<p>Impact of Side-Recess Length on the DC and RF Characteristics of GaAs Metamorphic High Electron Mobility Transistors (mHEMTs)</p> <p>Inseon Song¹, Ilhyeong Lee¹, Kyutae Kim¹, Geunuk Han¹, Yunji Jeong¹, Seung Heon Shin², Eun-Kyung Chu¹, Deok-Soo Park¹, Yumin Koh¹, Hyunchul Jang¹, and Jae-Phil Shim¹</p> <p>¹KANC, ²Soonchunhyang University</p>
WP-099	<p>Modulation of 2DEG for Highly Sensitive Magnetic Field Detection</p> <p>Cheng Han¹, Mingi Seo¹, Younghoon Kim¹, John Son³, and Junseok Heo^{1,2}</p> <p>¹Department of Intelligence Semiconductor Engineering, Ajou University, ²Department of Electrical and Computer Engineering, Ajou University, ³Genicom Co., Ltd</p>
WP-100	<p>CMOS Compatible SiGe Channel Photo BJT with High Responsivity and Efficiency</p> <p>Tae Young Yoon, Tae Woo Kim, Dong-Woo Jee, and Jang Hyun Kim</p> <p>Department of Intelligence Semiconductor Engineering, Ajou University</p>



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A Paradigm Shift in Semiconductors for AI Era

WP-101	<p>Electrical Characteristics Dependence on Gate-Drain Spacing for 1200 V-Class Applications of E-Mode GaN on Si Power Devices</p> <p>Arim Choi, Hoseok Yoo, Hyeok-Jun Lee, Minjoo Kim, Chuyoung Cho, and Dong-Hyun Kim</p> <p>KANC</p>
WP-102	<p>AlGaIn/GaN HEMT 소자의 절연막 형성 및 열처리에 따른 전기적 특성 변화</p> <p>김민주, 최아림, 유호석, 이혁준, 조주영, 김동현</p> <p>한국나노기술원</p>
WP-103	<p>6인치 Si 기판 기반 pGaIn/Al_{0.2}Ga_{0.8}N/GaN HEMT의 게이트 금속에 따른 전기적 특성 비교</p> <p>이혁준, 최아림, 유호석, 김민주, 조주영, 김동현</p> <p>한국나노기술원</p>
WP-104	<p>Optimization of Passivation Structures for High-Reliability GaN HEMT Operation</p> <p>Hoil Son¹, Donghan Kim¹, Junghee Lee³, Haechan Lee¹, Hyeongwoo Lee¹, Jeongil Kim², and Hongsik Park¹</p> <p>¹School of Electronic and Electrical Engineering, Kyungpook National University, ²Department of Semiconductor Engineering, Dong-A University, ³L&D Inc.</p>
WP-105	<p>E-Mode Power GaN HEMT 구동을 위한 GaN 기반 모노리식 게이트 드라이브 회로 설계 및 제작</p> <p>임진홍^{1,2}, 김동훈², 임준혁², 김종선², 차호영^{1,2}</p> <p>¹주식회사 칩스케이, ²홍익대학교</p>
WP-106	<p>Single Event Effects (SEE) Analysis and Radiation Resistance Evaluation of AlGaIn/GaN HEMTs Devices by Alpha Particles</p> <p>Soomin Kim¹, Dongwook Kim¹, Dongchan Kim², and Jongwook Jeon²</p> <p>¹Department of Display Engineering, Sungkyunkwan University, ²Department of Electronic and Electric Engineering, Sungkyunkwan University</p>
WP-107	<p>Low-Temperature Passivation of In_{0.53}Ga_{0.47}As/InP Mesa-Type Photodiodes</p> <p>Taekyun Kim¹ and Junseok Heo^{1,2}</p> <p>¹Department of Intelligent Semiconductor Engineering, Ajou University, ²Department of Electrical and Computer Engineering, Ajou University</p>



WP-108	<p>Effect of Diode Electrode Structure on the Efficiency of Betavoltaic Cells</p> <p>Jaewon Park^{1,2}, Hyeon-Tak Kwak¹, Dong-Seok Kim³, Hoe-Min Kwak¹, Huiyun Jung¹, Donghan Kim², Dong-Young Kim¹, Jeong-Gil kim⁴, Hongsik Park², Sung-Bum Bae¹, and Hyung-Seok Lee¹</p> <p>¹ETRI, ²School of Electronic and Electrical Engineering, Kyungpook National University, ³Korea Multi-Purpose Accelerator Complex, KAERI, ⁴Department of Semiconductor, Dong-A University</p>
WP-109	<p>Multi-Threshold Voltage GaN Device Development for GaN-Based Power ICs on a 200mm GaN-on-Si</p> <p>Junhyeok Lee, Min Su Cho, Nakwon Yu, Jihoun Jung, Minjae Yeom, Heesub Lee, Jonghyun Lee, Sanggi Lee, and Woochul Jeon</p> <p>DB HiTek</p>
WP-110	<p>AlGaIn/GaN의 금속 접합 열처리 시간에 따른 계면 반응 및 구조 분석</p> <p>최여진¹, 장승환¹, 박찬영¹, 안대규¹, 최다은¹, 임기식², 안성진¹</p> <p>¹국립금오공과대학교 신소재공학과, ²한국폴리텍대학</p>
WP-111	<p>AlGaIn/GaN 기반 비대칭 MSM 광검출기</p> <p>홍성호¹, 허준석²</p> <p>¹아주대학교 전자공학과, ²아주대학교 지능형반도체공학과</p>
WP-112	<p>β-Ga₂O₃ 기반 수직형 SBD를 활용한 저선량 X선 검출기</p> <p>김선재^{1,3}, 류흐영^{1,2}, 김형윤³, 박지현³, 전대우³, 황완식^{1,2}</p> <p>¹한국항공대학교 신소재공학과, ²한국항공대학교 스마트항공모빌리티학과, ³한국세라믹기술원</p>
WP-113	<p>Monolithic Integration of a GaAs VCSELs on a Si Photodiodes for Coaxial Time-of-Flight Sensing</p> <p>Wonjun Cho¹ and Junseok Heo^{1,2}</p> <p>¹Department of Intelligence Semiconductor Engineering, Ajou University, ²Department of Electrical and Computer Engineering, Ajou University</p>
WP-114	<p>Evaluation of Contact Properties of AlGaIn/GaN High-Electron-Mobility Transistor Using the Bridge-Contact Resistance Method</p> <p>Bogeun Son, Hyunjung Lee, and Hongsik Park</p> <p>School of Electronic and Electrical Engineering, Kyungpook National University</p>



WP-115	Fabrication of 4-Inch AlGaIn/GaN HEMT on SiC for RF Application Raksan Ko, Dong-Hyun Kim, Deoksoo Park, and Jaemoo Kim Device Technology Division, KANC
WP-116	High Breakdown Voltage for Vertical GaN PN Diode with Multi Step Mesa Junction Termination Extensions Dae-Hyun Son ¹ , Donghan Kim ¹ , Jaewon Park ^{1,2} , Huiyun Jung ² , Hyeon-Tak Kwak ² , Hoe-Min Kwak ² , Hongsik Park ¹ , Sung-Bum Bae ² , and Hyung-Seok Lee ² ¹ School of Electronic and Electrical Engineering, Kyungpook National University, ² ETRI
WP-117	Experimental Study on i-GaN Thickness Effects in GaN PiN Betavoltaic Cell Performance Huiyun Jung ¹ , Jae-Won Park ^{1,2} , Hyeon-Tak Kwak ¹ , Donghan Kim ² , Hoe-Min Kwak ¹ , Dong-Young Kim ¹ , Dong-Seok Kim ³ , Jeong-Gil Kim ⁴ , Hongsik Park ² , Sung-Bum Bae ¹ , and Hyung-Seok Lee ¹ ¹ Photonic/Wireless Devices Research Division, Thin GaN Materials & Device Creative Research Section, ETRI, ² School of Electronic and Electrical Engineering, Kyungpook National University, ³ KAERI, ⁴ Dong-A University
WP-118	Electrical Characteristics Analysis of GaN HEMTs with p-GaN Gate Depending on RTA Temperature Yeonsil Yang, Jinseop Kim, and Hyeon-Bhin Jo ICT Device and Packaging Center, KETI
WP-119	Ga₂O₃의 UVC 검출 특성을 활용한 불꽃감지센서 응용 가능성 류희중 ^{1,2} , 김선재 ² , 엄준성 ³ , 구희성 ³ , 박지현 ⁴ , 전대우 ⁴ , 황완식 ^{1,2} ¹ 한국항공대학교 스마트항공모빌리티학과, ² 한국항공대학교 신소재공학과, ³ (주)멤스, ⁴ 한국세라믹기술원
WP-120	Reliability Enhancement of GaN MIS-HEMTs via High-Pressure Annealing Songyi Han and Dae-Myeong Geum Department of Electrical and Computer Engineering, Inha University



WP-121	<p>Influence of CuO_x Radius on Breakdown Voltage of p-Type CuO_x / n-Type β-Ga₂O₃ Heterojunction Diodes</p> <p>Hyeon Cheol Kim¹, Sameer Pokhrel¹, V. Janardhanam², Chel-Jong Choi¹, and Kyu Hwan Shim^{1,3}</p> <p>¹School of Semiconductor and Chemical Engineering, Semiconductor Physics Research Center (SPRC), Jeonbuk National University, ²Department of Physics, School of Engineering, Dayananda Sagar University, ³R&D Division, Sigetronics, Inc.</p>
WP-122	<p>p-GaN Gate Recessed GaN HEMT with MIS Structure</p> <p>Jong-Hyeok Sim, Jinhyeong Park, and Ho-Young Cha</p> <p>School of Electronic and Electrical Engineering, Hongik University</p>
WP-123	<p>Photodiode based on Ga₂O₃ Nanowire Catalyst Synthesis</p> <p>Jung-Bok Lee, Min-Seok Jang, Hee-Jin Kim, Ju-Eun An, and Ho-Jun Lee</p> <p>Pusan National University</p>
WP-124	<p>p-GaN AlGaIn/GaN HEMT의 정확한 열화시험을 위한 소자특성 실시간 측정 최적화</p> <p>이서윤, 김형탁</p> <p>홍익대학교 전자전기공학부</p>
WP-125	<p>Femtosecond Mid-Infrared Cr:ZnS Laser Utilizing Graphene-ZnSe Saturable Absorber</p> <p>Seong Hyeon Kim¹, Seung Tae Song¹, Sang Yeop Jeong¹, Dong Ho Shin², Young Tea Chun¹, Fabian Rotermund³, and Won Bae Cho¹</p> <p>¹Department of Nano-Semiconductor Engineering, Korea Maritime & Ocean University, ²Digital Biomedical Research Division, ETRI, ³Department of Physics, KAIST</p>
WP-126	<p>E-Mode AlGaIn HEMTs Enabled by Polarization Engineering with p-AlGaIn Cap Layers</p> <p>Ju-Eun Yun, Ryeong-Eun Kim, Do-Hyung Yeo, and Ho-Young Cha</p> <p>School of Electronic and Electrical Engineering, Hongik University</p>



WP-127	<p>Contact-Area Engineering Using Patterned Anode Structures in Vertical GaN PIN Diode</p> <p>Min-Guk Han and Ho-Young Cha</p> <p>School of Electronic and Electrical Engineering, Hongik University</p>
WP-384	<p>High-Efficiency X-Band AlGaIn/GaN/AlN HEMTs Achieving 64.2 % PAE and 6.27 W/mm CW Output Power Density</p> <p>Donghan Kim¹, Jung-Hee Lee³, A-Hyun Lee², Jeong-Gil Kim², and Hongsik Park¹</p> <p>¹School of Electronic and Electrical Engineering, Kyungpook National University, ²Department of Semiconductor, Dong-A University, ³L&D Inc.</p>



2026-01-28(수), 10:00-19:00

(공식발표시간: 17:30-19:00)

ZONE1 (4층, 로비)

[WP] 포스터세션

F. Silicon and Group-IV Devices and Integration Technology 분과

WP-128	<p>A Study on the Reversed Thickness Dependence of the Memory Window in HZO-Based MIFIS FeFETs</p> <p>Kilhwa Pi^{1,2}, Min Kyu Yeom^{1,2}, Seunghoon Choi^{1,2}, Sanghyup Lee^{1,2}, and Cheol Seong Hwang^{1,2}</p> <p>¹Department of Materials Science and Engineering, Seoul National University, ²Inter-university Semiconductor Research Center, Seoul National University</p>
WP-129	<p>Development of Process Technology for 180 nm CMOS Multi-Project Wafer (MPW) Service</p> <p>Byeong-Hyeok Choi¹, Sung-Min Park¹, Jin Hyun Kim¹, Eunpa Won¹, Joong-Heon Kim¹, Daeyoung Kim¹, Juyoung An¹, Sangsoo Kim¹, Onyu Kim¹, Hyosang Kim¹, Changweon Lee¹, Joongsool Park¹, Youngsu Kim², and Sang Hyun Jung¹</p> <p>¹KANC, ²NNFC</p>
WP-130	<p>Fully CMOS-Compatible Analog Content-Addressable Memory Using Single-Poly Embedded Flash Memory</p> <p>Jeseung Jeong^{1,2}, Jonghyun Ko^{1,2}, WooSeong Roh^{1,2}, Jong-Ho Lee^{1,2}, and Gyuweon Jung^{1,2,3}</p> <p>¹Department of Electrical and Computer Engineering, Seoul National University, ²Inter-university Semiconductor Research Center, Seoul National University, ³School of Transdisciplinary Innovations, Seoul National University</p>
WP-131	<p>Separating Ferroelectric Negative Capacitance from High-k Contributions in Metal-Ferroelectric-Insulator-Semiconductor Structured Capacitor</p> <p>Subin Jung^{1,2}, Seunghoon Choi^{1,2}, and Cheol Seong Hwang^{1,2}</p> <p>¹Department of Materials Science and Engineering, Seoul National University, ²Inter-university Semiconductor Research Center, Seoul National University</p>



WP-132	<p>Random Telegraph Noise-Driven Probabilistic Bit in Polycrystalline Silicon Thin-Film Transistor</p> <p>Jun-Young Park, Seong-Hun Kim, and Joon-Kyu Han</p> <p>Department of Material Science and Engineering, Seoul National University</p>
WP-133	<p>Modeling and Process Design Guideline of Oxide Chemical Mechanical Planarization in CMOS Back-End-of-Line Process</p> <p>Min Seok Cha^{1,2} and Woo Young Choi^{1,2}</p> <p>¹Department of Electrical and Computer Engineering, Seoul National University, ²Inter-university Semiconductor Research Center, Seoul National University</p>
WP-134	<p>Integration and Validation of a Multi-Chip Floorplan with Process Monitoring on a 180nm CMOS MPW Platform</p> <p>Eunpa Won¹, Sung-Min Park¹, Jin Hyun Kim¹, Byeong-Hyeok Choi¹, Joong-Heon Kim¹, Daeyoung Kim¹, Juyoung An¹, Sangsoo Kim¹, Onyu Kim¹, Hyosang Kim¹, Changweon Lee¹, Joongsool Park¹, Youngsu Kim², and Sang Hyun Jung¹</p> <p>¹KANC, ²NNFC</p>
WP-135	<p>Annealing 온도에 따른 피드백 전계효과 트랜지스터 기반 확률 비트의 특성 변화 연구</p> <p>허효주, 조경아, 김상식</p> <p>고려대학교 전기전자공학과</p>
WP-136	<p>트리플 게이트 피드백 전계효과 트랜지스터로 구성된 로직-인-메모리 셀의 JK Latch 동작 연구</p> <p>설민혁, 조경아, 김상식</p> <p>고려대학교 전기전자공학과</p>
WP-137	<p>Probabilistic Bit와 Markov Random Fields Model을 이용한 Image Denoising 구현 연구</p> <p>강민구, 조경아, 김상식</p> <p>고려대학교 전기전자공학과</p>
WP-138	<p>삼중 게이트 피드백 전계효과 트랜지스터로 구성된 로직-인-메모리 셀의 3진법 NAND Gate 동작 연구</p> <p>김태완¹, 허효주¹, 전주희¹, 김동기², 이동형², 조경아¹, 김상식^{1,2}</p> <p>¹고려대학교 전기전자공학과, ²고려대학교 반도체시스템공학과</p>



WP-139	<p>삼중 게이트 피드백 전계효과 트랜지스터 기반 NANY/NCONS 게이트의 로직-인-메모리 동작 연구</p> <p>전윤수¹, 임재욱¹, 전주혁², 조경아², 김상식^{1,2}</p> <p>¹고려대학교 반도체시스템공학과, ²고려대학교 전기전자공학과</p>
WP-140	<p>Scaling Characteristics of Oxide-Based Vertical Channel Transistors for Gain-Cell Memory</p> <p>Hyeonho Gu¹, Haksoon Jung¹, Minho Park¹, Hyeonjin Lee², Yanfeng Zhao², Yongwoo Lee¹, Byungjo Kim², and Jimin Kwon^{1,2}</p> <p>¹Department of Electrical Engineering, UNIST, ²Graduate School of Semiconductor Materials and Devices Engineering, UNIST</p>
WP-141	<p>p-Si:H/n-Ga₂O₃ 이중 채널 기반 생체모방 시냅스 광 트랜지스터</p> <p>김용기¹, 윤영빈³, 신명훈^{1,2}</p> <p>¹한국항공대학교 항공전자정보공학부, ²한국항공대학교 우주시스템공학부, ³한국전자통신연구원 차세대반도체소자연구실</p>
WP-142	<p>Resistivity-Related Design of Zero-TCR Poly-Si Resistors From 130 nm to 28 nm HKMG CMOS Process</p> <p>Seungjun Boo, Jinhyuk Lee, Jonghyun Son, Dongmin Shin, Juri Kim, Changmin Jeon, and Ohkyum Kwon</p> <p>Samsung Foundry, Samsung Electronics Co., Ltd.</p>
WP-143	<p>Layered Trench Gate Exhibiting Source/Drain Over-Etch Immunity without Punch-Through Stopper</p> <p>Seungjoon Jeong and Changhwan Shin</p> <p>School of Electrical Engineering, College of Engineering, Korea University</p>
WP-144	<p>Optimized FlipFET Standard Cell Design for Reduced Gate Delay and Improved Routability</p> <p>Dongjin Wi¹, Minho Park¹, and Jimin Kwon²</p> <p>¹Department of Electrical Engineering, UNIST, ²Department of Electrical Engineering, Graduate School of Semiconductor Materials and Devices Engineering, UNIST</p>
WP-145	<p>Analysis of Gate-All-Around FET with Oxide Bottom-Up Structure to Reduce Parasitic Capacitance in Shallow Trench Isolation Region</p> <p>Sungho Yang and Changhwan Shin</p> <p>School of Electrical Engineering, College of Engineering, Korea University</p>



WP-146	<p>Effect of Annealing Atmosphere for Bottom Electrode Anneal on the Endurance of W/HZO/W Ferroelectric Capacitors</p> <p>Hyeonjung Park¹, Changwoo Han², and Changhwan Shin²</p> <p>¹Department of Electrical and Computer Engineering, Sungkyunkwan University, ²School of Electrical Engineering, College of Engineering, Korea University</p>
WP-147	<p>Characteristics of GIDL Erase-Induced Hot Carrier Injection in Vertical NAND Flash Memory</p> <p>Jae Hyun Nam^{1,2}, Jin Ho Chang^{1,2}, Kyung Moon Kim^{1,2}, Da Eun Yang^{1,2}, Ji Sun Baek^{1,2}, Suk-Kang Sung³, and Woo Young Choi^{1,2}</p> <p>¹Department of Electrical and Computer Engineering, Seoul National University, ²Inter-university Semiconductor Research Center, Seoul National University, ³Advanced Flash Technology Team, Samsung Electronics Co., Ltd.</p>
WP-148	<p>Latch-Up Voltage Modulation by Applying Adaptive Pulse on Charge-Trap Based Floating-Body Transistor</p> <p>Taeho Lee^{1,2}, Jonghyun Ko^{1,2}, Jiseong Im^{1,2}, and Jong-Ho Lee^{1,2}</p> <p>¹Department of Electrical and Computer Engineering, Seoul National University, ²Inter-university Semiconductor Research Center, Seoul National University</p>
WP-149	<p>Inner Spacer Effects on Stress and Parasitic Capacitance in Gate-All-Around Nanosheet FETs: A TCAD Framework Using Kinetic Monte Carlo Epitaxy</p> <p>NaYun Kim^{1,2} and Jiwon Chang^{1,2}</p> <p>¹Department of System Semiconductor Engineering, Yonsei University, ²BK21 Graduate Program in Intelligent Semiconductor Technology</p>
WP-150	<p>Additional Oxidation Treatment를 통한 5V NMOS TDDb 개선</p> <p>황수진, 강형근, 이도현, 김선구, 남명희, 박정수</p> <p>Department of Technology Development, SK hynix systemic (wuxi) solutions, Co., Ltd.</p>
WP-151	<p>3-Tier CFET 6T-SRAM With 2D-TMDCs Channels With Double-Sided Interconnect and Backside PDN for Angstrom Technology Node</p> <p>Jonghun Lee¹, Seungmin Jun², and Jongwook Jeon²</p> <p>¹Department of Display Engineering, Sungkyunkwan University, ²Department of Electrical and Computer Engineering, Sungkyunkwan University</p>



WP-152	<p>Enhanced Electrical Performance of GOI nMOSFETs via Laser-Annealing-Induced Source/Drain Activation and Tensile Strain</p> <p>Minseo Song¹, Hojin Jeong², Hyeonrak Lim², and Sanghyeon Kim²</p> <p>¹Graduate School of Semiconductor Technology, KAIST, ²School of Electrical Engineering, KAIST</p>
WP-153	<p>From Vulnerability to Robustness: Radiation-Hard Isolation for BPR-Enabled Stacked Nanosheet CFETs</p> <p>Dongwook Kim¹, Sumin Kim¹, and Jongwook Jeon²</p> <p>¹Department of Display Engineering, Sungkyunkwan University, ²Department of Electrical and Computer Engineering, Sungkyunkwan University</p>
WP-154	<p>Enhanced Responsivity of CuInSe₂ Quantum Dot-Coated Silicon Photodetectors</p> <p>Juwon Yun¹, Neunghye Han², Seonyoung Park¹, Jihun Lee¹, Woonhyuk Baek³, and Kihyun Kim^{1,4}</p> <p>¹Department of Electronics and Information Engineering, Jeonbuk National University, ²Department of Semiconductor Science and Technology, Jeonbuk National University, ³School of Semiconductor and Chemical Engineering, Jeonbuk National University, ⁴Division of Electronic Engineering, Jeonbuk National University</p>
WP-155	<p>Frequency-Tunable THz Detector Design with Embedded Varactor Stacking for Detecting Sensitivity</p> <p>Gi Yong Lee¹, Yoo Bin Song^{1,3}, Tae Hwan Hyeon², Min Woo Ryu^{1,3}, and Kyung Rok Kim^{1,3}</p> <p>¹Department of Electrical Engineering, UNIST, ²Graduate School of Semiconductor Materials and Devices Engineering, UNIST, ³Ternell Corp.</p>
WP-156	<p>A 28-nm Ternary-SRAM Macro with Highly Bit-Dense Bitline Reduction Architecture and Energy-Efficient Single-Ended 8T Access Operation</p> <p>Myoung Kim^{1,2}, Yesong Jeong^{1,2}, Woo-Seok Kim¹, Junyoung Park¹, Sang Hun Yeo¹, In Jun Jang¹, Kwan Yong Lee², Min Woo Ryu^{1,2}, and Kyung Rok Kim^{1,2}</p> <p>¹Department of Electrical Engineering, UNIST, ²Ternell Corp.</p>



WP-157	<p>Development of a Next-Generation CFET PDK Considering Backside Power Delivery Network (BSPDN)</p> <p>JuneYeop Lee¹, Jihye Yoo¹, Gaon Lee², and Jongwook Jeon¹</p> <p>¹Department of Electrical and Computer Engineering, Sungkyunkwan University, ²Department of Display Engineering, Sungkyunkwan University</p>
WP-158	<p>Enhancing Sensitivity of FET-Based Trantenna through Aperture Design</p> <p>Tae Hwan Hyeon¹, Yoo Bin Song^{2,3}, Gi Yong Lee², Min Woo Ryu^{2,3}, and Kyung Rok Kim^{2,3}</p> <p>¹Graduate School of Semiconductor Materials and Devices Engineering, UNIST, ²Department of Electrical Engineering, UNIST, ³Ternell Corp.</p>
WP-159	<p>Transparent Optical Power Monitoring Using Thin InGaAs Membrane MSM Photodetector</p> <p>Jaehyeon An^{1,2}, Jinil Lee¹, Kyunghwan Kim¹, Hojoong Jung¹, Jae-Hoon Han¹, SangWook Han¹, Myung-Jae Lee², and DaeHwan Ahn¹</p> <p>¹Center for Quantum Technology, KIST, ²Department of Electrical and Electronic Engineering, Yonsei University</p>
WP-160	<p>An Area-Efficient TCAM Cell Based Ternary Latch with Hybrid Operation</p> <p>Jun Young Park¹, Woo-Seok Kim¹, Myoung Kim^{1,2}, Yesong Jeong¹, Sang Hun Yeo¹, Kwan Yong Lee¹, In Jun Jang¹, Min Woo Ryu^{1,2}, and Kyung Rok Kim^{1,2}</p> <p>¹Department of Electrical Engineering, UNIST, ²Ternell Corp.</p>
WP-161	<p>Study of Tensile Strain Formation in Rapid-Melting-Growth Germanium under Different SiO₂ Capping Conditions</p> <p>Dong Woo Lee, Jongmin Son, Hyeseo Park, Youngmin Kim, and Donghwan Ahn</p> <p>School of Materials Science & Engineering, Kookmin University</p>
WP-162	<p>Tunneling-Based 3D Ternary CMOS Technology for Highly Reliable, Low-Power, and High-Density SRAM Toward Sustainable SoC Design</p> <p>Woo-Seok Kim¹, Sang Hun Yeo¹, Kwan Yong Lee², Myoung Kim^{1,2}, In Jun Jang¹, Junyoung Park¹, Yesong Jeong^{1,2}, Min Woo Ryu^{1,2}, and Kyung Rok Kim^{1,2}</p> <p>¹Department of Electrical Engineering, UNIST, ²Ternell Corp.</p>



WP-163	<p>TCAD-Based Variability Analysis and Optimization in 28-nm Gate-Underlap Ternary CMOS Technology</p> <p>Kwan Yong Lee¹, Woo-Seok Kim², Sang Hun Yeo², In Jun Jang², Myoung Kim^{1,2}, Yesong Jeong^{1,2}, Junyoung Park², Min Woo Ryu^{1,2}, and Kyung Rok Kim^{1,2}</p> <p>¹Ternell Corp., ²Department of Electrical Engineering, UNIST</p>
WP-164	<p>Ultra-Thin La₂O₃ Interfacial Layer for TDDb Lifetime Extension in HZO Ferroelectric Devices</p> <p>HyeonCheol Jeong¹, KyungSoo Park ², Yoonseok Lee¹, Yeonwoo Choi¹, SangMyun Lim¹, JiHoon Choi¹, Taesuk Kim², and Changhwan Choi^{1,2}</p> <p>¹Department of Semiconductor Engineering, Hanyang University, ²Division of Materials Science and Engineering, Hanyang University</p>
WP-165	<p>Short-Channel Effect Immune and Ultra-Low Power Steep-Slope Ternary CFET/GAA Architecture for Edge-AI Applications</p> <p>Sang Hun Yeo¹, Woo-Seok Kim¹, Kwan Yong Lee², In Jun Jang¹, Myoung Kim^{1,2}, Jun Young Park¹, Yesong Jeong^{1,2}, Min Woo Ryu^{1,2}, and Kyung Rok Kim^{1,2}</p> <p>¹Department of Electrical Engineering, UNIST, ²Ternell Corp.</p>
WP-166	<p>Bias-Temperature Instability Characteristics of High-k Metal Gate Ternary CMOS Technology</p> <p>In Jun Jang¹, Woo-Seok Kim¹, Sang Hun Yeo¹, Kwan Yong Lee², Myoung Kim^{1,2}, Junyoung Park¹, Yesong Jeong^{1,2}, Min Woo Ryu^{1,2}, and Kyung Rok Kim^{1,2}</p> <p>¹Department of Electrical Engineering, UNIST, ²Ternell Corp.</p>
WP-167	<p>Protocol-Compatible Ternary Bus for Energy-Efficient On-Chip Interconnects</p> <p>Yesong Jeong^{1,2}, Myoung Kim^{1,2}, Woo-Seok Kim¹, Jun Young Park¹, Sang Hun Yeo¹, Kwan Yong Lee², In Jun Jang¹, Min Woo Ryu^{1,2}, and Kyung Rok Kim^{1,2}</p> <p>¹Department of Electrical Engineering, UNIST, ²Ternell Corp.</p>
WP-168	<p>High-Speed Terahertz Detector for Large-Area Low-Noise Imaging System</p> <p>Yoo Bin Song^{1,3}, Tae Hwan Hyeun², Gi Yong Lee¹, Min Woo Ryu^{1,3}, and Kyung Rok Kim^{1,3}</p> <p>¹Department of Electrical Engineering, UNIST, ²Graduate School of Semiconductor Materials and Devices Engineering, UNIST, ³Ternell Corp.</p>



WP-169	<p>Compact Modeling of CFET Devices Including N/PMOS and Intermediate RC Network</p> <p>Gaon Lee¹, Hojin Kim³, Woonwoo Kim², Jihye Yoo⁴, Juneyeop Lee⁴, and Jongwook Jeon²</p> <p>¹Department of Display Engineering, Sungkyunkwan University, ²Department of Electrical and Computer Engineering, Sungkyunkwan University, ³Department of Semiconductor Convergence Engineering, Sungkyunkwan University, ⁴Device Research Laboratory (SKKU-DRL), Sungkyunkwan University</p>
WP-170	<p>Impact of Doping Concentration in the Lightly-Doped Drain on Gate-Induced Drain Leakage of Ultra-Thin-Body MOSFET</p> <p>Erica Soomin Kim^{1,2} and Seongjae Cho^{1,2}</p> <p>¹Division of Electronic and Semiconductor Engineering, Ewha Womans University, ²Institute for Multiscale Matter and Systems (IMMS), Ewha Womans University</p>



2026-01-28(수), 10:00-19:00

(공식발표시간: 17:30-19:00)

ZONE1 (4층, 로비)

[WP] 포스터세션

M. RF and Wireless Design 분과

WP-191	<p>3D-Printed AiP Lid Substrates with Coaxial Through-Via Feeds for Improved High-Frequency Signal Integrity</p> <p>Kyungsun Kim¹, Nahyeon Kim¹, Haksoon Jung², Yongwoo Lee², and Jimin Kwon^{1,2}</p> <p>¹Graduate School of Semiconductor Materials and Devices Engineering, UNIST, ²Department of Electrical Engineering, UNIST</p>
WP-192	<p>A Bandgap-Referenced Wide-Swing Current-Mode VCSEL Driver in 0.18-μm CMOS for Low-Cost Short-Range LiDAR Sensors</p> <p>Yiyao Li, Yu Hu, Sieun Choi, Suwon Cho, Somi Park, Sunkyung Lee, Bobin Seo, and Sung Min Park</p> <p>Division of Electronic & Semiconductor Engineering, Ewha Womans University</p>
WP-193	<p>A Low-Noise CMOS Active-Feedback Transimpedance Amplifier with a Low-Dropout Regulator based on Flipped Voltage Follower</p> <p>Suwon Cho, Sieun Choi, Yiyao Li, Bobin Seo, Somi Park, Sunkyung Lee, Yu Hu, and Sung Min Park</p> <p>Division of Electronic & Semiconductor Engineering, Ewha Womans University</p>
WP-194	<p>RF Power Transfer Efficiency Measurement System for Stable Plasma Processing in Semiconductor Manufacturing</p> <p>Narim Lee¹, Dongjun Min¹, Hyunjun Kim¹, Hyunjoo Hwang², Wonwoo Kho², Namjun Kang³, and Seung-Eon Ahn^{1,2}</p> <p>¹Department of Nano & Semiconductor Engineering, Tech University of Korea, ²Department of IT · Semiconductor Convergence Engineering, Tech University of Korea, ³ion RESEARCH</p>



WP-195	<p>Design of a 28-nm FD-SOI Differential Low-Noise Amplifier for 6G Front-End Applications</p> <p>Geunwoo Park¹, Chaeyun Kim², Bohyeon Kim², and Changkun Park^{1,2}</p> <p>¹School of Electronic Engineering, Soongsil University, ²Department of Intelligent Semiconductor, Soongsil University</p>
WP-196	<p>K-Band CMOS Voltage-Controlled Oscillator for Millimeter-Wave Signal Generation</p> <p>Ji-Ho Yoo¹, Hyeon-Jin Son², and Jong-Ryul Yang^{1,2}</p> <p>¹Department of Electronics and Electrical Engineering, Konkuk University, ²Millisight Technologies Co., Ltd.</p>
WP-197	<p>First Heterogeneous and Monolithic 3D (HM3D) Integration of InGaAs HEMTs and InP/InGaAs DHBTs on Si CMOS for Next-Generation Wireless Communication</p> <p>Nahyun Rheem¹, Jaeyong Jeong¹, Yoon-Je Suh¹, Chan Jik Lee¹, Bong Ho Kim^{1,2}, Joon Pyo Kim^{1,2}, Seong Kwang Kim^{1,2}, Hyeonrak Lim¹, Jongmin Kim³, Dae-Hwan Ahn⁴, Jae-Hoon Han⁴, Jongwon Lee⁵, and Sanghyeon Kim¹</p> <p>¹School of Electrical Engineering, KAIST, ²Samsung Electronics Co., Ltd., ³KANC, ⁴Center for Opto-Electronics Materials and Devices, KIST, ⁵Department of Semiconductor Convergence, Chungnam National University</p>
WP-198	<p>에너지 효율적인 딜레이 라인 기반 LO와 커패시턴스 펄스 셰이핑을 이용한 사이드 로브 저감 IR-UWB 송신기</p> <p>김민성, 권익진</p> <p>아주대학교 전자공학과</p>
WP-199	<p>Modeling Large-Signal RF Behavior Considering Self-Heating and Trap Effects</p> <p>Wonwoo Kim¹, Changho Ra¹, Dongchan Kim¹, Jaejoon Woo², and Jonguk Jeon¹</p> <p>¹Department of Electrical and Computer Engineering, Sungkyunkwan University, ²Department of Semiconductor Convergence Engineering, Sungkyunkwan University</p>



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[WP] 포스터세션

T. AI 분과

WP-339	<p>Efficient Analog Computing-in-Memory Macro for Block Floating Point Number Format</p> <p>Wonkyung Han¹, Dohyun Kim¹, Jihoon Park¹, Juheun Lee², Wonjun Han², and Jae-Joon Kim^{1,2}</p> <p>¹Department of Electrical and Computer Engineering, Seoul National University, ²Interdisciplinary Program in Artificial Intelligence, Seoul National University</p>
WP-340	<p>Analysis of Group-Wise Quantized Element Distributions Across Different Workloads</p> <p>Do Hyun Kim and Jae Joon Kim</p> <p>Department of Electrical and Computer Engineering, Seoul National University</p>
WP-341	<p>M_xFP₄ Dot-Product Engine with Configurable Depth Tree Reduction</p> <p>Wonjun Han and Jae-Joon Kim</p> <p>Interdisciplinary Program in Artificial Intelligence, Seoul National University</p>
WP-342	<p>A Schmitt-Trigger Comparator-Based Noise-Robust Reconfigurable Leaky Integrate-and-Fire Neuron Circuit for Spiking Neural Networks</p> <p>Chae-Hwan Park^{1,2}, Seung Yoon Shin^{1,2}, Seong Eun Kim^{1,2}, Min Kang^{1,2}, and Soo-Yeon Lee^{1,2}</p> <p>¹Department of Electrical and Computer Engineering, Seoul National University, ²Inter-university Semiconductor Research Center, Seoul National University</p>
WP-343	<p>An Efficient LUT-Based FP₁₆ Exponential Function Approximation for LLM Accelerators</p> <p>최성우, 이제훈, 이주찬, 김재준</p> <p>서울대학교 전기·정보공학부</p>



WP-344	<p>Random Point Sampling for Faster LiDAR Semantic Segmentation Inference</p> <p>Gyeongseok Hyeon and Injae Yoo</p> <p>School of Electrical and Electronics Engineering, Pusan National University</p>
WP-345	<p>Artificial Neuronal Arithmetic based on Ovonic Threshold Switches for Biologically-Inspired Analog Computation</p> <p>Jingyeong Hwang^{1,2}, Unhyeon Kang^{1,2}, Seungmin Oh^{1,3}, Jiin Bang^{1,4}, Kyungmin Lee^{1,5}, Younghyun Lee¹, Hakseung Rhee⁶, Jooyoung Bae¹, and Suyoun Lee^{1,4}</p> <p>¹Center for Semiconductor Technology, KIST, ²Department of Materials Science and Engineering, Seoul National University, ³Department of Physics and Astronomy, Seoul National University, ⁴Nanoscience and Technology, Korea National University of Science and Technology, ⁵Department of Electrical Engineering, Korea University, ⁶Department of Materials Science and Engineering, KAIST</p>
WP-346	<p>Demonstration of the Hopfield Associative Network Using Cu-Ge₂Te₁ CBRAM Array</p> <p>Jiin Bang^{1,2}, Jingyeong Hwang^{2,3}, Unhyeon Kang^{2,3}, Seungmin Oh^{2,4}, Kyungmin Lee^{2,5}, Hakseung Rhee⁶, Younghyun Lee², Jooyoung Bae², and Suyoun Lee^{1,2}</p> <p>¹Nanoscience and Technology, University of Science and Technology, ²Center for Semiconductor Technology, KIST, ³Department of Materials Science and Engineering, Seoul National University, ⁴Department of Physics and Astronomy, Seoul National University, ⁵Department of Electrical Engineering, Korea University, ⁶Department of Materials Science and Engineering, KAIST</p>
WP-347	<p>ROM 시냅스 기반 면적 최소화형 확률적 SNN</p> <p>이승준^{1,4}, 금건우^{1,4}, 김윤^{2,4,5}, 구민석^{3,4,5}</p> <p>¹서울시립대학교 지능형반도체학과, ²서울시립대학교 전자전기컴퓨터공학부, ³서울시립대학교 첨단융합학부, ⁴서울시립대학교 반도체 연구센터, ⁵주식회사 IM전자</p>
WP-348	<p>듀얼게이트 가우시안 트랜지스터를 이용한 MLP 구현</p> <p>유영우^{1,2}, 조준형³, 유호천⁴, 김영준^{1,2}</p> <p>¹가천대학교 반도체공학과, ²가천대학교 전자공학과, ³한양대학교 인공지능반도체공학과, ⁴한양대학교 융합전자공학과</p>



제 33회 한국반도체학술대회

The 33rd Korean Conference on Semiconductors

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A Paradigm Shift in Semiconductors for AI Era

WP-349	<p>Vision Transformer 모델의 최적 토큰 프루닝 레이어 선택을 위한 조건부 계층적 탐색 프레임워크</p> <p>이승주, 김병수</p> <p>한국전자기술연구원 SoC플랫폼연구센터</p>
WP-350	<p>Performance-Latency Analysis of RAG Systems in On-Device Environments</p> <p>Wonjun Hwang, Seungil Lee, and Hyun Kim</p> <p>Department of Electrical and Information Engineering, Research Center for Electrical and Information Technology, Seoul National University of Science & Technology</p>
WP-351	<p>Reinforcement Learning Architecture based on Train-Inference Chains for Resource Optimization</p> <p>Junghwan Choi, Dohyun Kim, and Shiho Kim</p> <p>School of Integrated Technology, BK21 Graduate Program in Intelligent Semiconductor, Yonsei University</p>
WP-352	<p>Evaluating Throughput of KV-Cache Offloading Across Memory Tiers</p> <p>Juchan Lee, Hyunjin Kim, Jiwon Song, and Jae-Joon Kim</p> <p>Department of Electrical and Computer Engineering, Seoul National University</p>
WP-353	<p>Ternary MAC Architecture with Scaling for Energy-Efficient NPU Design</p> <p>김도윤, 송다예, 정서현</p> <p>국민대학교 전자공학부</p>
WP-354	<p>A Comparative Analysis of DRAM Architectures for Efficient Test-Time Adaptation in Convolutional Layers</p> <p>Jeongho Kim, Jin Shin, and Hyun Kim</p> <p>Department of Electrical and Information Engineering, Research Center for Electrical and Information Technology, Seoul National University of Science & Technology</p>
WP-355	<p>Vertical Si/SiGe/Si Biristor-Based P-Bits for Probabilistic Computing</p> <p>Jaeseoung Park, Jong Pil Im, Hanchan Song, Wangjoo Lee, Jeong Woo Park, and Dongwoo Suh</p> <p>ETRI</p>



WP-356	<p>Advancing Semiconductor Reliability through AI and FFT-Enhanced Photo-Induced Current Transient Spectroscopy (PICTS)</p> <p>Saegyong Song¹, Hui Gu Lee², Byeongchan Sim¹, Minju Kim¹, Dong Il Kim¹, Hyunwee Cho¹, and Jinpyo Hong^{1,2}</p> <p>¹Department of Physics, Hanyang University, ²Division of Nano-scale Semiconductor Engineering and Physics, Hanyang University</p>
WP-357	<p>Improving Hardware Efficiency of the Fault Detector for Sliding-Window CNN Accelerator</p> <p>Doan Khue Do, Chunmyung Park, Xuan Truong Nguyen, and Hyuk-Jae Lee</p> <p>Department of Electrical and Computer Engineering, Seoul National University</p>
WP-358	<p>Lightweight FRC-Aware Mixed Quantization for Robust Edge Speech Recognition</p> <p>Hanul Ryu, Minsu Kim, Sungho Lee, and Mingeon Shin</p> <p>KETI</p>
WP-359	<p>Hardware Architecture Optimization for Winograd Convolution-Based Edge AI Accelerator</p> <p>Minsu Kim, Hanul Ryu, Mingeon Shin, and Sungho Lee</p> <p>Convergence Signal SoC Research Center, KETI</p>
WP-360	<p>A Neuromorphic Compute-in-Memory Processor for Efficient Acceleration of SlipReLU-Based ANN-to-SNN Converted Spiking ResNet-18</p> <p>Seolhyeon Kim, Suk-Min Yoon, and Min-Seong Choo</p> <p>Department of Electronic Engineering, Hanyang University</p>
WP-361	<p>Interface Tuning of HfO_x/TaO_x Multilayered Memristor for Implementation of Noise-Aware Neural Network</p> <p>Seung Kyu Kang¹, Sungmin Yu^{1,2}, Sang Min Lee^{1,3}, Suyoun Lee¹, Jong-Keuk Park¹, and Inho Kim¹</p> <p>¹Center for Semiconductor Technology, KIST, ²Display and Nanosystem Laboratory, School of Electrical Engineering, Korea University, ³Department of Micro/Nano Systems, Korea University</p>

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ZONE1 (4층, 로비)

[WP] 포스터세션

U. Bio-Medical 분과

WP-362	<p>Nernst-Planck Model-Based Simulation for Design and Performance Prediction of Iontophoretic Devices</p> <p>Jongho Cho¹, Dongjun Han², Hyemi Lee³, Hyungjun Choi¹, Kyeungbin Kim¹, and Dong-Wook Park²</p> <p>¹Department of Electrical and Computer Engineering, University of Seoul, ²School of Electrical and Computer Engineering, University of Seoul, ³Department of BioHealth and Eco-Up convergence, University of Seoul</p>
WP-363	<p>반도체 공정을 활용한 SERS 바이오 센서 제작</p> <p>김수근^{1,2}, 강영호^{1,3}</p> <p>¹전남대학교 물리교육과, ²전남대학교 광전자융합기술연구소, ³전남대학교 양자기술연구소</p>
WP-364	<p>sEMG 신호의 On-Chip 특징 추출을 위한 VCO-Based Analog Front End 설계</p> <p>유희재^{1,3}, 구민석^{2,3,4}, 김윤^{1,3,4}</p> <p>¹서울시립대학교 전자전기컴퓨터공학과, ²서울시립대학교 첨단융합학부, ³서울시립대학교 반도체연구센터(UOS-FAB), ⁴주식회사 IM전자</p>
WP-365	<p>Microwave-Processed PZTO Membrane with Plasma-Enhanced Surface Adhesion: From Thin Film to Nanofiber Structure for High-Sensitivity pH</p> <p>Seung Jin Lee, Seung-Hwa Choi, and Won-Ju Cho</p> <p>Department of Electronic Materials Engineering, Kwangwoon University</p>
WP-366	<p>A Bias-Free and Ultra-Low Interrogation Power RF Biosensor based on Cu-MOF for Dopamine Detection</p> <p>Yoongi Cho¹, Sung moon Park², Seungchan Lee², and Myungsoo Kim^{1,2}</p> <p>¹Graduate School of Semiconductor Materials and Devices Engineering, UNIST, ²Department of Electrical and Computer Engineering, UNIST</p>



WP-367	<p>MEMS-Fabricated Silicon Nanocolumn CMUT Arrays for Flexible and Disposable Ultrasound Patches</p> <p>Seonghun Cho^{1,2}, Dong-Hyun Kang^{1,3}, Hae Youn Kim¹, Shinyong Shim¹, Dong Hun Kim¹, Baren Jeong⁴, Yoon Seong Lee⁴, Eun-Ah Park⁴, Whal Lee⁴, Hyungmin Kim¹, Butrus T. Khuri-Yakub⁵, Maesoon Im^{6,7,8}, Jae-Woong Jeong², and Byung Chul Lee^{1,7,8}</p> <p>¹Bionics Research Center, KIST, ²School of Electrical Engineering, KAIST, ³Department of Mechanical Engineering, Gangneung-Wonju National University, ⁴Department of Radiology, Seoul National University Hospital, ⁵Department of Electrical Engineering, Stanford University, ⁶Brain Science Institute, KIST, ⁷Division of Bio-Medical Science and Technology, KIST School, University of Science and Technology, ⁸KHU-KIST Department of Converging Science and Technology, Kyung Hee University</p>
WP-368	<p>췌장암 치료를 위한 3차원 자가적응, 삽입형 마이크로 LED 소자Self-Adaptive, Three-Dimensional Implantable MicroLEDs for Pancreatic Cancer Therapy</p> <p>Minseo Kim, Jae Hee Lee, and Keon Jae Lee</p> <p>Department of Materials Science and Engineering, KAIST</p>
WP-369	<p>G-ISFET 의 Dirac Point 산포를 줄이기 위한 인터페이스 회로 IP</p> <p>Sohyeon Ahn, Kwang Soup Song, and Ji-Yong Um</p> <p>Department of Medical IT Convergence Engineering, Kumoh National Institute of Technology</p>



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ZONE2-1 (5층, 로비)

[WP] 포스터세션

Q. Metrology, Inspection, Analysis, and Yield Enhancement 분과

WP-220	<p>초고속 상관 화학기계연마 계측을 위한 위상 이동 간섭계와 능동 탐침 주사 탐침 현미경 통합 기술</p> <p>유준호, 장재영</p> <p>넥센서</p>
WP-221	<p>반도체 생산라인의 Optical Inspection 장비에서 Beam Alignment 동작 분석 기반의 생산성 향상 및 산포 저감 전략</p> <p>신호섭^{1,2,3}, 신동균⁴</p> <p>¹성균관대학교 반도체디스플레이공학과, ²삼성전자 메모리사업부, ³Samsung Advanced Institute of Technology, ⁴성균관대학교 소프트웨어 컴퓨터 공학과</p>
WP-222	<p>Rapid Analysis of SiGe Composition by Wide-Field Raman Spectroscopy</p> <p>Chanwoo Kim and Hyuksang Kwon</p> <p>KRISS</p>
WP-223	<p>차세대 3D 반도체 공정을 위한 오토인코더 기반 오버레이 계측 정밀도 향상 기법</p> <p>이현철^{1,3}, 장현진¹, 우호성², 이원규³</p> <p>¹오로스테크놀로지, ²한국방송통신대학교, ³고려대학교</p>
WP-224	<p>Development of a Z-Pinch Plasma Source-Based Testing Platform for Optical Characterization of Materials Used in Extreme Ultraviolet Lithography</p> <p>Eun-Seok Choe^{1,2}, Wooram Kim¹, Do-Yeon Hwang^{1,4}, Hee-Jung Yeom¹, Jinhoo Seong^{1,4}, Gwang-Seok Chae^{1,4}, Young-Gi Kim³, Hyo-Chang Lee⁴, Hyun-Dam Jeong⁵, Won Chegal^{1,6}, Dong-Wook Kim², and Jung-Hyung Kim¹</p> <p>¹Semiconductor and Display Metrology Group, KRISS, ²Department of Radio and Information Communications Engineering, Chungnam National University, ³Korea Institute of Fusion Energy, ⁴Department of Semiconductor Science, Engineering and Technology, Korea Aerospace University, ⁵Department of Chemistry, Chonnam National University, ⁶Graduate School of Analytical Science and Technology, Chungnam National University</p>



제 33회 한국반도체학술대회

The 33rd Korean Conference on Semiconductors

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A Paradigm Shift in Semiconductors for AI Era

WP-225	<p>Development of an Extreme Ultraviolet Light Source via Dual-Pulse Laser-Produced Plasma for EUV Lithography Material Evaluation Systems</p> <p>Do-Yeon Hwang^{1,2}, Wooram Kim¹, Eun-Seok Choe¹, Chegal Won¹, Young-Gi Kim³, Hyo-Chang Lee^{2,4}, and Jung-Hyung Kim¹</p> <p>¹KRISS, ²Department of Semiconductor Science, Engineering and Technology, Korea Aerospace University, ³Korea Institute of Fusion Energy, ⁴School of Electronics and Information Engineering, Korea Aerospace University</p>
WP-226	<p>절연체 기반 유전영동을 이용한 반도체 공정용 화학물질 내 나노입자 정제 기술</p> <p>이승윤¹, 장진혁², 오준영², 김영훈², 최삼종², 김윤호², 김지현¹</p> <p>¹서울대학교 화학생물공학부, ²삼성전자 소재기술팀</p>
WP-227	<p>Quantitative Hydrogen Analysis by Time of Flight-Elastic Recoil Detection Analysis (TOF-ERDA) Using Medium Energy Ion</p> <p>Kyungsu Park, Jwa Soon Kim, Jiho Song, Haejoon Hahm, Soobang Kim, Jong Hun Kim, and Won Ja Min</p> <p>HB Solution Co., Ltd.</p>
WP-228	<p>광섬유 전단력 현미경 기반 초고분해능 열영상 이미징 기술</p> <p>정문경, 김동욱, 정찬배, 김동목, 장기수</p> <p>한국기초과학지원연구원 연구장비개발부</p>
WP-229	<p>Electrical Property Enhancement in MOCVD-Grown MoS₂ FETs: Comparative Insights into Contact Strategies</p> <p>Junghyun Lee^{1,2}, Sanghwa Lee^{1,2}, Hyunwoo Kim^{1,2}, Bongjoong Kim², and Jun Oh Kim²</p> <p>¹KRISS, ²Hongik University</p>
WP-230	<p>Design and Optimization of Quasi-3D Hole Array Nanostructures for High-Efficiency Plasmonic Filters</p> <p>Tae-kyung Im^{1,2}, Jehwan Hwang³, Hyunwoo Kim^{1,2}, Sanghwa Lee^{1,2}, Bongjoong Kim², and Jun Oh Kim¹</p> <p>¹KRISS, ²Mechanical Engineering, Hongik University, ³Optical Lens Materials Research Center, KOPTI</p>



WP-231	<p>Comparative Study of Channel Geometry and Electrical Performance in MoS₂ FETs</p> <p>Hyunwoo Kim^{1,2}, Do Kyung Kim³, Junghyun Lee^{1,2}, Sangwha Lee^{1,2}, Bongjoong Kim², and Jun Oh Kim¹</p> <p>¹KRISS, ²Hongik University, ³Kangwon National University</p>
WP-232	<p>E-Beam Generated Fast-Traps in MoS₂ Transistors through Transient I-V Characterization</p> <p>Joonyup Bae¹, Sunghan Cho^{1,2}, Nagyeong Lee¹, and Jihyun Kim¹</p> <p>¹Department of Chemical and Biological Engineering, Seoul National University, ²Global Manufacturing and Infra Technology, Samsung Electronics Co., Ltd.</p>
WP-233	<p>Thermal Property Imaging for 3D Packaging Using Frequency-Domain Thermoreflectance</p> <p>Dongyun Seo, Jihyun Kim, Kyusung Han, and Jungwan Cho</p> <p>School of Mechanical Engineering, Sungkyunkwan University</p>
WP-234	<p>Diffraction Diversity 향상을 통한 EUV Ptychography 이미지 복원 성능 개선 연구 홍준호^{1,3}, 문승찬^{2,3}, 이태호³, 안진호^{1,2,3}</p> <p>¹한양대학교 신소재공학과, ²한양대학교 나노반도체공학과, ³극한스케일·극한물성-이종 집적 한계극복 반도체 기술 연구센터</p>
WP-235	<p>4D-STEM과 EELS을 이용한 Hf_{0.5}Zr_{0.5}O₂ 강유전상에서의 산소공공 분포와 상안정화 상관성 분석</p> <p>성민찬¹, 정지훈¹, 이기용¹, 박범수², 이성호¹, 정지원¹, 오상호¹</p> <p>¹한국에너지공과대학교 에너지공학부, ²삼성전자 반도체연구소</p>
WP-236	<p>Micron-Scale Thermal Property Characterization Using Thermo-Optic Phase Spectroscopy (TOPS)</p> <p>Kyusung Han, Jihyun Kim, Taeyeon Kim, Dongyun Seo, and Jungwan Cho</p> <p>School of Mechanical Engineering, Sungkyunkwan University</p>
WP-237	<p>Non-Destructive Material Characterization Using a Compact Multispectral LWIR Imaging Module</p> <p>Jejung Lee¹, Yonghun Cho¹, Danwon Lee¹, Gimin Bae², and Young Hwa Lee¹</p> <p>¹Next-Generation C5 System Department, Institute of Innovation for Future Army, ²DDOK, Co. Ltd.</p>



WP-238	<p>Quantitative Evaluation of Probe Current Stability in Scanning Electron Microscopes for Semiconductor Metrology</p> <p>Ha Rim Lee¹, Youngkwon Haam^{1,3}, Junhyeok Hwang¹, Jeong-Woong Lee¹, Haewon Jung¹, Hoon Kang¹, Junhyeong Park¹, Hyunmo Gu¹, Insu Seo¹, and In-Yong Park^{1,2,3}</p> <p>¹Strategic Technology Research Institute, KRISS, ²Major in Nanoconvergence Measurement, University of Science and Technology, ³Graduate School of Analytical Science and Technology, Chungnam National University</p>
WP-239	<p>Voltage Contrast Inspection of an Electrical Defect on a Semiconductor Wafer with X-Ray Photoelectron Spectroscopy and an Electron Beam</p> <p>Gyungtae Kim¹, Tae Gun Kim¹, Chil-sung Jung¹, Yunju Oh¹, and Bongjin Simon Mun²</p> <p>¹NNFC, ²GIST</p>
WP-240	<p>Artificial Neural Network-Based Detection of In-Cell Region Pattern Non-Uniformity</p> <p>ChangHwan Lee, SeuRi Jeong, and DkNyon Lee</p> <p>SK hynix Inc.</p>
WP-241	<p>Metrology and Inspection을 위한 SEM 이미지 복원 및 응용</p> <p>황준혁, 이정웅, 박인용, 오가와 타카시</p> <p>한국표준과학연구원 미래선도연구장비그룹</p>
WP-242	<p>Johnsen-Rahbek형 정전척의 표면 형상에 따른 Chucking Mechanism 고찰</p> <p>김범수, 조지훈, 김창훈</p> <p>(주)보부하이테크</p>
WP-243	<p>3D 구조 하부 결함 분석을 위한 In-Line 파괴 검사 기법 개발</p> <p>Do Young Choi, Jae Cheol Jo, and Kyu Young Kim</p> <p>SK Hynix Inc.</p>
WP-244	<p>Effect of Sulfur Passivation on the Electrical Characteristics of InGaAs-InP Heterojunction TFET</p> <p>Jong Hwan Park, Min Su Kim, Dong Hwi Choi, Jae Hyeop Lee, and Jae Cheol Shin</p>



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A Paradigm Shift in Semiconductors for AI Era

Department of Electronics and Electrical Engineering, Dongguk University



WP-245	<p>Enhancing Yield and Variability Control of 8-Inch CMOS-Compatible RRAM for Mass Production Applications</p> <p>Heesoo Yang, Woo-Seok Kim, Bonseong Gu, Youna Kwon, Sanghwa Lee, Won-chul Lee, Dong-wook Lee, Seung Jong Yoo, Gap Sup Sim, Young Joo Kim, Woo-Suk Sul, and Kanghyeok Jeon</p> <p>NNFC</p>
WP-246	<p>Fabrication of a Laser-Integrated TEM Holder and Drift Benchmarking toward In-Situ Micro Solder Bump</p> <p>Yun Jae Jung, Hui Won Park, Ye Rim Kang, Hyun Jin Choi, Jin Young Kim, and Young Heon Kim</p> <p>Department of Analytical Science and Technology, Graduate School of Analytical Science and Technology, Chungnam National University</p>
WP-247	<p>Analysis of EUV Light Source based on the Cold Cathode Electron Beam Irradiation with Multilayer Mirror Measurement for Actinic Inspection Technique</p> <p>Iksu Kim, Umesh Balaso Apugade, Dana Chung, and Kyu Chang Park</p> <p>Department of Information Display, Kyung Hee University</p>
WP-248	<p>Development and Assessment of an Air-Free Transfer Holder for Reliable TEM Characterization of Air-Sensitive Semiconductors</p> <p>Hui Won Park, Yun Jae Jung, and Young Heon Kim</p> <p>Graduate School of Analytical Science and Technology, Chungnam National University</p>
WP-249	<p>Microstructural Property and Formation Mechanism of Cracks in AlInN/GaN Heterostructure</p> <p>Chan Hee Hwang¹, Da Mi Kwon¹, Hyeon Jin Choi¹, Jong Hoon Kim¹, Eun Ah Cheon², Young Kyun Noh², and Young Heon Kim¹</p> <p>¹Graduate School of Analytical Science and Technology, Chungnam National University, ²IVWorks Co., Ltd.</p>
WP-250	<p>Pellicle Inspection Technique based on the EUV Light Source with Cold Cathode Electron Beam</p> <p>Umesh Balaso Apugade, Iksu Kim, and Kyu Chang Park</p> <p>Department of Information Display, Kyung Hee University</p>
WP-251	<p>Fabrication and Reliable Evaluation of MEMS Heating Chips for In-Situ TEM</p>



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A Paradigm Shift in Semiconductors for AI Era

	<p>Ji Min Lee¹, Jin Young Kim¹, Dae Yeon Kim¹, Yun Jae Jung¹, Hui Won Park¹, Hoil Cha², Jong Cheol Park², Yun Chang Park², and Young Heon Kim¹</p> <p>¹Department of Analytical Science and Technology, Graduate School of Analytical Science and Technology, Chungnam National University, ²NNFC</p>
WP-252	<p>Optical and Electronic Responses of 2D van der Waals Heterostructures Probed by Temperature-Dependent Infrared Ellipsometry</p> <p>Sukhyun Choi, Yongjai Cho, Junghoon Yang, Jongkyoon Park, and Won Chegal</p> <p>Semiconductor and Display Metrology Group, KRISS</p>
WP-253	<p>플라즈마 식각 환경에서 이트륨계 소재의 오염입자 발생 실시간 분석 연구</p> <p>이래원^{1,3}, 민병현^{1,2}, 강상우^{1,2}, 김태성³, 문지훈¹</p> <p>¹한국표준과학연구원 전략기술연구소, ²과학기술연합대학교대학원 정밀측정, ³성균관대 학교 성균나노과학기술원</p>



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[WP] 포스터세션

S. Chip Design Contest 분과

WP-254	<p>A Half-VDD Biased Capacitively Driven On-Chip Link With Switched-Capacitor Signaling</p> <p>Wonbin Lee¹, Soonwon Kwon², In-Woo Jang¹, Jae-Seung Jeong^{1,3}, Sara Kim¹, and Kyeongha Kwon¹</p> <p>¹KAIST, ²MediaTek, ³Samsung Electronics Co., Ltd</p>
WP-255	<p>An 850μW, 2-to-5GHz Jitter-Filtering and Instant-Toggling Injection-Locked Quadrature-Clock Generator for Low-Power Clock Distribution in HBM Interfaces</p> <p>Jeongbeom Seo¹, Yuhwan Shin², and Jaehyouk Choi¹</p> <p>¹Department of Electrical and Computer Engineering, Seoul National University, ²Electrical Engineering, KAIST</p>
WP-256	<p>A 0.4-VDDQ 11.5-Gb/s/pin Transmitter with Switched-Coupling Charge-Pump Crosstalk Cancellation Achieving Eye-Margin Recovery for Ultra-Dense Die-to-Die Interfaces</p> <p>Yoochang Kim¹ and Young-Ha Hwang^{1,2}</p> <p>¹Department of Intelligent Semiconductors, Soongsil University, ²School of Electronic Engineering, Soongsil University</p>
WP-257	<p>A Low-Power 8-b 500MS/s Three-Comparator SAR ADC with Background Comparator-Swapping Offset Calibration</p> <p>Seunghyun Kim and Minjae Lee</p> <p>School of Electrical Engineering and Computer Science, GIST</p>
WP-258	<p>A Temperature-Compensated LDO with Embedded Voltage Reference for Compact SoCs in 65nm CMOS</p> <p>Beomsoo Kim¹, Yuli han², and Kunhee Cho¹</p> <p>¹Department of Semiconductor Convergence Engineering, Sungkyunkwan University, ²DB Global Chip</p>



WP-259	Small-Area, High-Speed, and High Uniformity Source Driver IC for OLED-on-Silicon (OLEDoS) Displays Jung Hwan Oh, Wi Man Yoo, Dong Kun Lee, and Jong Seok Kim Department of Electronics and Electrical Engineering, Hanyang University ERICA
WP-260	A High-Efficiency Low-Ripple Pulse-Frequency Modulation Buck Converter for Light-Load Applications Gang-Bae Park, So-Hyun Lee, Hye-Seon Choi , and Jong-Seok Kim Department of Electrical and Electronic Engineering, Hanyang University ERICA
WP-261	In-Memory-Computing Architecture for Closed-Loop Peripheral Nerve Modulation Implants Donghyeon Yi ¹ , Seoyoung Lee ² , and Minkyu Je ¹ ¹ School of and Electrical Engineering, KAIST, ² IMEC
WP-262	An Energy-Efficient Multi-Cell Battery Charger with Simultaneous Charging and Balancing Seongil Yeo and Kunhee Cho Department of Semiconductor Convergence Engineering, Sungkyunkwan University
WP-263	Second-Order Feedforward $\Delta\Sigma$ Converter for High-Sampling-Rate Current-Type Bio Signal Measurement Minseok Park and Chul Kim Department of Bio and Brain Engineering, KAIST
WP-264	A 100-Mb/s TIA-first Galvanic-Coupling Communication Receiver for Neural Implant Systems 이현엽, 이동윤, 정윤철, 제민규 한국과학기술원 전기 및 전자공학부
WP-265	A Design Technique for Highly Parallel PRTS Generators Jusung Park and Jintae Kim Konkuk University
WP-266	Single-Photon Avalanche Diode Based X-Ray Detector Hyun-Seung Choi and Youngcheol Chae Yonsei University



WP-267	A Design Technique for Linearity Enhanced Dynamic Amplifier Gwangmin Jung and Jintae Kim Konkuk University
WP-268	An Energy-Efficient Keyword Spotting Processor with Zero-Aware Feature Skipping and Relaxed Convolution Sangyeon Kim ¹ , Seongmin Ki ¹ , and Sungju Ryu ² ¹ Department of Electronic Engineering, Sogang University, ² Department of System Semiconductor Engineering, Sogang University
WP-269	A Single-Ended PAM-3 Transmitter with Multiplexing Driver for Memory Interfaces Chan-Hee Jeon and Yong-Un Jeong School of Semiconductor Systems Engineering, Sejong University
WP-270	A 9.4-fs-FoM Fast Transient Switched-Capacitor LDO in 28-nm CMOS Sangwoong Sim, Donghwan Kim, and Jaehoon Jun Department of Electrical and Computer Engineering, Inha University
WP-271	Mutual Locking of Buffered Oscillators via Inter-Core Line 김준성, 김문일 고려대학교 초고주파 연구실
WP-272	A V-Band Vector Sum Phase Shifter over a Wide Band Width in 28nm CMOS Technology Hyeong Jin An and Chul Woo Byeon ¹ Department of Electronic and Electrical Engineering, Dankook University
WP-273	A V-band Power Divider/Combiner with a Tunable Isolation Band Using a Capacitor Bank in 28nm CMOS Technology Yeon Soo Lim and Chul Woo Byeon Department of Electronic and Electrical Engineering, Dankook University
WP-274	A V-Band 2-Stage Low-Phase-Error Variable Gain Amplifier with 0.5dB Resolution of 24dB Gain Range in 65nm CMOS Technology In Cheol Yoo and Chul Woo Byeon Department of Electronic and Electrical Engineering, Dankook University



제 33회 한국반도체학술대회

The 33rd Korean Conference on Semiconductors

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A Paradigm Shift in Semiconductors for AI Era



WP-275	<p>Time-Interleaved Nyquist and Delta-Sigma Current-Steering DACs for Wireless Transmitter</p> <p>Hyunyoung Yoo¹, Yeonsu Kim¹, Su-Hyeon Kim¹, Eunji Yoo¹, Gu-Hyeon Lee¹, Jae-Yun Park², and Jae-Won Nam¹</p> <p>¹Department of Electronic Engineering, Seoul National University of Science & Technology, ²Agency for Defense Development</p>
WP-276	<p>Design of Analog Front-End for the Wideband Wireline Receiver</p> <p>Hyunyoung Yoo¹, Su-Hyeon Kim¹, Yeonsu Kim¹, Eunji Yoo¹, Gu-Hyeon Lee¹, Jae-Yun Park², and Jae-Won Nam¹</p> <p>¹Department of Electronic Engineering, Seoul National University of Science & Technology, ²Agency for Defense Development</p>
WP-277	<p>Gate- and Body-Driven OLEDos Pixel Circuit for a Wide Data Range</p> <p>Chanjin Park and Soo-Yeon Lee</p> <p>Department of Electrical and Computer Engineering, Seoul National University</p>
WP-278	<p>Energy-Efficient Compression Architecture for Molecular Dynamics</p> <p>Seongmin Ki, Sangyeon Kim, and Sungju Ryu</p> <p>Sogang University</p>
WP-279	<p>A Low-Dropout Regulator Using Gain-Boosting OTA and Dynamic Feedback Compensation for Low Power DRAM Cores</p> <p>Min Cheol Kim, Ju Hong Min, and Jang Hyun Kim</p> <p>Department of Intelligence Semiconductor Engineering, Ajou University</p>
WP-280	<p>Scalable Neuromorphic Architecture with STDP based on Chip Learning for Edge Devices</p> <p>SuHwan Na, SungHyun Cha, and DongSun Kim</p> <p>Department of Semiconductor Systems Engineering, Sejong University</p>
WP-281	<p>A 5V-Input 0.6-to-2.2V Output 3 Level Step-Down Converter Using Open Loop Based Flying Capacitor Voltage Balancing for DDR5 VRoD PMICs</p> <p>최정진¹, 이정섭², 윤제훈¹, 유승완¹, 최우석¹, 이강윤¹</p> <p>¹성균관대학교 전자전기컴퓨터공학과, ²성균관대학교 반도체디스플레이공학과</p>
WP-282	<p>A 90GHz Passive Mixer-First Receiver in 28-nm CMOS</p> <p>최규빈, 노승모, 최우열</p> <p>서울대학교 전기정보공학부</p>



WP-283	<p>12-Bit High Resolution–Area Efficient Current DAC</p> <p>Dong Hun Cha¹, Ji Seong Kim², Se Woong Jeong¹, Yu Jin Lee¹, and Jeong Hoan Park^{1,2}</p> <p>¹Department of Semiconductor Engineering, Kyung Hee University, ²Department of Electronic Engineering, Kyung Hee University</p>
WP-284	<p>Reconfigurable Regulating Rectifier with Minimized Conduction and Switching Loss in 130nm BCDMOS</p> <p>신도현, 홍진우, 허준영, 김지민, 김종민, 범진욱</p> <p>Department of Electronic Engineering, Sogang University</p>
WP-285	<p>High-Speed and Highly Reliable 3-T Embedded NOR Flash Memory for Standard CMOS Process</p> <p>Min Se Kim^{1,2}, Jae Seung Woo^{1,2}, and Woo Young Choi^{1,2}</p> <p>¹Department of Electrical and Computer Engineering, Seoul National University, ²Inter-university Semiconductor Research Center, Seoul National University</p>
WP-286	<p>Biopotential Amplifier with SNR–Optimizing Technique under Harsh Contact Impedance Conditions</p> <p>Younghun Jeong and Nhamil Koo</p> <p>School of Foundry Engineering, Dankook University</p>
WP-287	<p>Compact Integration of RDAC and High-Pass Filter for Battery Electrochemical Impedance Spectroscopy</p> <p>ByeongHo Hwang¹, UiKyoung Lee¹, JiHan Shin², and KyeongHa Kwon^{1,2}</p> <p>¹School of Electrical Engineering, KAIST, ²Graduate School of AI Semiconductor, KAIST</p>
WP-288	<p>Energy-Efficient Ternary Content-Addressable Memory based on One Capacitor and One Nanoelectromechanical Memory Switch Memory Cell</p> <p>Myeong Su Shin^{1,2}, Geun Tae Park^{1,2}, Jin Wook Lee^{1,2}, and Woo Young Choi^{1,2}</p> <p>¹Department of Electrical and Computer Engineering, Seoul National University, ²Inter-university Semiconductor Research Center, Seoul National University</p>



WP-289	<p>Nanoelectromechanical Physically Unclonable Function for Resource-Constrained IoT Environments</p> <p>Seung Hun Baek^{1,2}, Jin Wook Lee^{1,2}, Geun Tae Park^{1,2}, and Woo Young Choi^{1,2}</p> <p>¹Department of Electrical and Computer Engineering, Seoul National University, ²Inter-university Semiconductor Research Center, Seoul National University</p>
WP-290	<p>Low-Power Analog CMOS Neuron Circuits for Solving Fan-in Issues in Spiking Neural Network Systems</p> <p>Seongjin Kim^{1,2,3}, Jonghyuk Park^{1,2}, Yeonwoo Kim^{1,2}, and Woo Young Choi^{1,2}</p> <p>¹Department of Electrical and Computer Engineering, Seoul National University, ²Inter-university Semiconductor Research Center, Seoul National University, ³Flash Design Team, Samsung Electronics Co., Ltd.</p>
WP-291	<p>A 20 GHz Integer-N PLL with Injection-Locked Frequency Divider-by-4 in 28 nm CMOS</p> <p>Young Jun Byun, Min Gi Seo, and Gyungsu Byun</p> <p>Department of Electrical and Computer Engineering, Inha University</p>
WP-292	<p>A Low-Power CMOS Non-Linear DDS for Non-Faradaic EIS Biosensors</p> <p>Jun-Seok Beom, Kang-Woo Choi, and Nam-Seog Kim</p> <p>School of Information and Communication Engineering, Chungbuk National University</p>
WP-293	<p>Design of Polysilicon Grating Couplers Using Metal Reflector in FD-SOI Platform</p> <p>Jiwi Park, Chaewon Jeon, and Kyoungsik Yu</p> <p>KAIST</p>
WP-294	<p>A High-Voltage Double Step-Down Converter with Perturb & Observe MPPT Technique in Solar PV System</p> <p>Tae-Ryeong Kim and Jong-Wook Lee</p> <p>Department of Electronic Engineering, Kyung Hee University</p>
WP-295	<p>Micro-Bolometer Thermal Imager with Ambient Temperature Compensated Sensor Sensitivity</p> <p>Jongho Jung, Taehyung Kim, Kiwon Seo, and Gunhee Han</p> <p>School of Integrated Technology, Yonsei University</p>



WP-296	<p>Design of W-band Power Amplifier and Low-Noise Amplifier for High-Speed Dielectric Waveguide Link</p> <p>이영한, 이성준, 최우열</p> <p>서울대학교 전기정보공학부</p>
WP-297	<p>A Dual Supply-Ground Voltage Regulation Scheme Using Low-Dropout Regulators for CMOS SoCs</p> <p>Hee-Cheol Joo¹ and Young-Ha Hwang^{1,2}</p> <p>¹Department of Intelligent Semiconductors, Soongsil University, ²School of Electronic Engineering, Soongsil University</p>
WP-298	<p>Differential Sense Amplifier Integrating Precharge and Offset Compensation Process</p> <p>Chaebin Kim¹ and Keewon Kwon²</p> <p>¹Department of Electronic and Electrical Engineering, Sungkyunkwan University, ²Department of Semiconductor System Engineering, Sungkyunkwan University</p>
WP-299	<p>HVLS-Based Cell-Selective EIS Structure for Series-Connected Multi-Cells</p> <p>Ayeon Gwon, Yeseul Song, and Junwon Jeong</p> <p>Sookmyung Women's University</p>
WP-300	<p>DC-DC Converter with Pulse-Skip Mode for Low-Power Operation</p> <p>Minseok Kim, Haechan Park, Jiho Jung, Minkwang Ji, Jooyun Oh, Sungwan Hong, Jihun Oh, Heejun Byeon, Huiseung Chae, Jaehyeok Lee, Kyungseok Lee, and Joongho Choi</p> <p>University of Seoul</p>
WP-301	<p>A Second-Order Noise-Shaping SAR ADC with 3-Level-Switching CDACs Employing a Novel DWA</p> <p>김준형, 나우성, 조장현, 최보성, 고경보, 권준석, 박상규</p> <p>한양대학교 융합전자공학과</p>
WP-302	<p>A K-Band Doherty Power Amplifier with Transformer-Based Matching Network for 6G and Beyond Wireless Communication</p> <p>이성준, 김준엽, 최우열</p> <p>서울대학교 전기정보공학부</p>



WP-303	<p>An Error Correcting Code Encoder Utilizing Orthogonal Latin Square Code for HBM Application</p> <p>Yue Ri Jeong, Sangho Lee, Seongmo An, Jinyeol Kim, and Seung Eun Lee Department of Electronic Engineering, Seoul National University of Science & Technology</p>
WP-304	<p>Gray Code Counter-Based Loopback Verification Framework for RCD Control Word Functionality in 28nm CMOS</p> <p>Saransh Rajjarwal, Min-Gi Seo, Young-Jun Byun, and Gyung Su Byun Department of Electrical and Computer Engineering, Inha University</p>
WP-305	<p>Input Bus Termination Calibration with Digital Controller Design for High-Speed Memory Interface</p> <p>Saransh Rajjarwal, Min-Gi Seo, Young-Jun Byun, and Gyung Su Byun Department of Electrical and Computer Engineering, Inha University</p>
WP-306	<p>8-Way FDM-Based 500 MHz BW DDFS for a Baseband Qubit Controller</p> <p>Hyunyoung Yoo¹, Su-Hyeon Kim¹, Muhammad Fakhri Mauludin², Yeonsu Kim¹, Eunji Yoo¹, Gu-Hyeon Lee¹, Jae-Yun Park³, Jusung Kim⁴, and Jae-Won Nam¹ ¹Department of Electronic Engineering, Seoul National University of Science & Technology, ²Department of Electronics Engineering, Hanbat National University, ³Agency for Defense Development, ⁴Division of Electronic and Semiconductor Engineering, Ewha Womans University</p>
WP-307	<p>가변 부하 배터리 밸런싱을 위한 High-VDS, Low-on Stacked CMOS Switch IC</p> <p>이규환, 최동국, 최수로, 김상혁, 이경태 Department of Electrical Engineering and Computer Science, DGIST</p>
WP-308	<p>A Sub-1-V Bandgap Reference Circuit with High PSRR</p> <p>Minoo Lee, Gahyeon Sung, and Junghyup Lee DGIST</p>
WP-309	<p>Low-Power Wideband 4.8-7.2 GHz Balun-LNA with Local Feedback gm-Boosting and Current-Bleeding for Wi-Fi 7 Applications</p> <p>Youngchae Lee, Chaerin Park, and Kuduck Kwon Department of Electronic Engineering, Kangwon National University</p>



WP-310	A Blocker-Tolerant Balun-LNTA with Integrated Dual-Band LC Notch Filter for Sub-6 GHz 5G NR Receivers Sejin Lee, Seungyeon Kim, and Kuduck Kwon Department of Electronic Engineering, Kangwon National University
WP-311	A Dual-Band N-Path Balun-LNA for 5G New Radio Cellular Applications Byounghyun You, Heesu Lee, and Kuduck Kwon Department of Electronic Engineering, Kangwon National University
WP-312	A Pipelined ADC With a Gain-Boosted Dynamic Amplifier Bo Gao, Raymond Mabilangan, and Seung-Tak Ryu School of Electrical Engineering, KAIST
WP-313	Design and Analysis of a Cascaded Floating Inverter Amplifier Based 2nd-Order Noise-Shaping SAR ADC Jang Su Hyeon and Hyeon June Kim Seoul National University of Science & Technology
WP-314	A Hybrid Recording System with 10kHz-BW 630mVpp 84.6dB-SNDR 173.3dB-FOMSND and 5kHz-BW 114dB-DR for Simultaneous ExG and Biocurrent Acquisition Seokhan Jeong ¹ , Taeryoung Seol ² , and Junghyup Lee ¹ ¹ DGIST, ² Georgia Institute of Technology
WP-315	A 7T1C 5644 PPI OLED on Silicon Pixel Circuit with 1.2V and 5.5V Transistors in 28nm CMOS Process Hyeon-Ji Lee, Chang-Hun Lee, and Byong-Deok Choi Department of Electronic Engineering, Hanyang University
WP-316	A Wide-Lock-In-Range and Low-Jitter 12-14.5 GHz SSPLL Using a Low-Power Frequency-Disturbance-Detecting and Correcting Loop Young Jun Kim, Si Heon Lee, Tae Hyub Kim, and Younghyun Lim School of Semiconductor Engineering, Kyung Hee University
WP-317	A Calibration-Free VCO-$\Delta\Sigma$ ADC with PVT-Insensitive Frequency-Locked Differential Regulation Scheme for Multi-Channel ExG Acquisition Sehwan Lee ^{1,2} , Kyuhyeon Park ¹ , and Junghyup Lee ¹ ¹ DGIST, ² Samsung Electronics Co., Ltd.



WP-318	<p>ADC-Free Neuron based on Page Buffer for Bit-Sliced Neuromorphic Systems</p> <p>Jinhyeok Kim^{1,4}, Yoon Kim^{1,3,4}, and Minsuk Koo^{2,3,4}</p> <p>¹School of Electrical and Computer Engineering, University of Seoul, ²School of Advanced Fusion Studies, University of Seoul, ³IM Electronics co., ⁴Center for Semiconductor Research, University of Seoul</p>
WP-319	<p>Hybrid LDO Having Small-Output Ripple and Fast Settling at 0.5V Supply Using Dynamic Gate-Voltage Generation and Fast-PD Decision</p> <p>Seungwan Kim and Younghyun Lim</p> <p>School of Semiconductor Engineering, Kyung Hee University</p>
WP-320	<p>Design of Programmable-Gain Amplifier for Precise Measurement of Dielectric Absorption Voltage Recovery in On-Chip Capacitors</p> <p>Joo-Sun Lee, Yong-Jin Kim, and Byong-Deok Choi</p> <p>Department of Electronic Engineering, Hanyang University</p>
WP-321	<p>60GHz Dual-Core Class-F Push-Push VCO with Dual Path Voltage Control</p> <p>Joon-Hyuk Moon, Ye-Won Jeon, Jun-Kyo Park, Tae-Jeong Kim, and Byung-Sung Kim</p> <p>RF Microelectronic Design Lab., Sungkyunkwan University</p>
WP-322	<p>LPDDR 인터페이스용 NRZ/PAM-4 듀얼 모드 송신기 설계</p> <p>김승균¹, 조항민², 이원영¹</p> <p>¹서울과학기술대학교 스마트ICT융합공학과, ²한국전자통신연구원</p>
WP-323	<p>A SiC MOSFET Gate Driver Employing an Adaptive Soft Turn-Off Current and a Current Slope-to-Digital Converting Technique</p> <p>Geonwoo Park¹, Jinman Myung¹, Yoseph Kim¹, Seungjik Lee², and Ilku Nam¹</p> <p>¹Department of Electrical Engineering, Pusan National University, ²Analog Devices Korea</p>
WP-324	<p>A Compact Fractional Output Divider with Time-Multiplexed INL Detection Achieving -75 dBc Worst-Case Spur over 0.64-0.90 V</p> <p>Jiwon Shin, Yoona Lee, and Woo-Seok Choi</p> <p>Department of Electrical and Computer Engineering, Seoul National University</p>



WP-325	A D-Band Compact, Power Efficiency X8 Frequency Multiplier With 112–172 GHz Output 3–dB Bandwidth in 28–nm Bulk CMOS Dong–Yeol Yang, Ye–won Jeon, and Byung–Sung Kim RF Microelectronic Design Lab., Sungkyunkwan University
WP-326	Design of a Hybrid Step–Down Converter with Inductor Current Reduction Seungjin Baek ¹ , Seunghoon Lee ¹ , Jusung Kim ² , and Kunhee Cho ¹ ¹ Department of Semiconductor Convergence Engineering, Sungkyunkwan University, ² Division of Electronic and Semiconductor Engineering, Ewha Womans University
WP-327	CTCAM–Based HW Friendly Image Classification Model 김동휘, 김수민, 임현기, 박주환, 최연우, 서영석, 홍상훈 경희대학교 전자공학과
WP-328	A Galvanically Isolated High Speed Switching Gate Driver for Low–to–Medium Voltage Wide–Bandgap Semiconductor Sangin Choi and Kunhee Cho Department of Semiconductor Convergence Engineering, Sungkyunkwan University
WP-329	A 12–b Fully–Differential Ring–Amp–Based 100–MS/s Pipelined SAR ADC Jisu Kim ¹ , Taeho Lee ² , and Jun–Eun Park ¹ ¹ Department of Electrical and Computer Engineering Sungkyunkwan University, ² Department of Semiconductor Convergence Engineering Sungkyunkwan University
WP-330	Wideband High–Performance CMOS Cascode Frequency Down Converters Hosung Kang, Seungyun Han, and Jihoon Kim Kyonggi University
WP-331	Skew–Detecting Method for Time–Interleaved SAR ADC Joonhyun Park and Hyungil Chae Konkuk University



WP-332	A 56-Gb/s PAM4 Receiver Using Injection-Based Baud-Rate CDR With Jointly Adaptive AFE 박민수, 전정훈 Department of Electrical and Computer Engineering, Sungkyunkwan University
WP-333	전압 결합 방식 및 전류 결합 방식 동시에 사용된 밀리미터파 CMOS 도허티 전력증폭기 설계 빈수현, 최영찬, 양영구 성균관대학교 전자전기컴퓨터공학과
WP-334	An eMRAM-Based True Random Number Generator Using a Digitally Controlled Delay Line Seunghwa Hyun and Jongsun Park Department of Electrical Engineering, Korea University
WP-335	Wireless Network of Distributed Neural Interface Joonyoung Lim, Jong-hyun Park, Gwang-ho Choi, Seok-won Joo, and Yoon-Kyu Song Graduate School of Convergence Science and Technology, Seoul National University
WP-336	Adaptive Spike Detecting Circuit for Wireless Brain Implant Neural Interface IC Joonyoung Lim, Jong-hyun Park, Gwang-ho Choi, Seok-won Joo, and Yoon-kyu Song Graduate School of Convergence Science and Technology, Seoul National University
WP-337	Feasibility Validation of a Domain-Specific Accelerator Integrated into an Open-Source RISC-V SoC Dowon Kim, Dongbeom Son, Dongeon Won, and Jungwook Choi Hanyang University
WP-338	D-Band Frequency Multiplier for Wireless Communications in 28-nm CMOS FDSOI Process 김재관 ¹ , 서문교 ² ¹ 성균관대학교 반도체융합공학과, ² 성균관대학교 전자전기공학부



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A Paradigm Shift in Semiconductors for AI Era

WP-385

A 97.5%-Efficiency Hybrid Dual-Path Buck Converter with Self-Balancing

Hyeon Gyu Park and Young-Kyun Cho

Department of Radio and Information and Communication Engineering,
Chungnam National University



2026-01-28(수), 10:00-19:00

(공식발표시간: 17:30-19:00)

ZONE2-2 (5층, 로비)

[WP] 포스터세션

C. Material Growth & Characterization 분과

WP-036	<p>Doping-Dependent Ferroelectric Properties of Al Doped HfO₂ Thin Films for FeFET Applications</p> <p>Hyun Gon Pyo^{1,2} and Cheol Seong Hwang^{1,2}</p> <p>¹Department of Materials Science and Engineering, Seoul National University, ²Inter-university Semiconductor Research Center, Seoul National University</p>
WP-037	<p>Overcoming Intrinsic Thermal Instability in MoS₂ Monolayer via High-Pressure CVD Growth</p> <p>Seok joon Yun and Takmo Jeong</p> <p>University of Ulsan</p>
WP-038	<p>공정 변수의 복합적 제어를 통한 고결정성·저결함 MoS₂ 박막의 합성</p> <p>황준연, 원종서, 이재원, 허정윤, 홍웅기</p> <p>단국대학교 파운드리공학과</p>
WP-039	<p>Atomic Layer Deposition of Molybdenum Carbide and Substrate-Dependent Reduction to Metallic Molybdenum.</p> <p>안광용¹, 구본욱¹, Kieran G Lawford², Seán T. Barry², and Han-Bo-Ram Lee¹</p> <p>¹Department of Material Science and Engineering, Incheon National University, ²Department of Chemistry, Carleton University</p>
WP-040	<p>Stoichiometry-Engineered Binary Chalcogen Thin Films Enabled by Integrated Synthetic Approach</p> <p>Gayeon Lee¹, Namwook Hur², Changhwan Kim², Seonguk Yang¹, and Joonki Suh¹</p> <p>¹Department of Chemical and Biomolecular Engineering, KAIST, ²Department of Materials Science and Engineering, UNIST</p>



WP-041	<p>Study on the Efficiency of Deuterium Annealing for Various Process Durations</p> <p>Min-Woo Kim, Hyo-Jun Park, Eui-Cheol Yun, Sang-Min Kang, Da-Eun Bang, Dol Sohn, and Jun-Young Park</p> <p>School of Semiconductor Engineering, Chungbuk National University</p>
WP-042	<p>Highly Crystalline ZrO₂ Films under 2 nm by Atomic Layer Modulation</p> <p>Wonjoong Kim¹, Ngoc Le Trinh¹, Bonwook Gu¹, Dohyun Kim¹, Byung-ha Kwak², Hyun-Mi Kim³, Hyeongkeun Kim³, Youngho Kang¹, Il-Kwon Oh², and Han-Bo-Ram Lee¹</p> <p>¹Department of Materials Science and Engineering, Incheon National University, ²Department of Electrical and Computer Engineering, Ajou University, ³Electronic Convergence Materials and Devices Research Center, KETI</p>
WP-043	<p>Multi-Zone Thermally Decoupled MOCVD for Low-Temperature MoS₂ Synthesis</p> <p>Jongseo Won, Jaewon Lee, Jungyoon Hur, Junyeon Hwang, and Woonggi Hong</p> <p>Department of Foundry Engineering, Dankook University</p>
WP-044	<p>Van der Waals High-k Crystalline Lanthanum Oxychloride Integration for Superior Switching 2D Transistor</p> <p>Changjun Park¹, Habin Baek², Hanbin Cho¹, Jing Huang³, Kyungmin Ko⁴, Chanhoo Lee², Sangwoo Park², Soobeom Shin², Hu Young Jeong², Jun Kang³, and Joonki Suh¹</p> <p>¹Department of Chemical & Biomolecular Engineering, KAIST, ²Graduate School of Semiconductor Materials and Devices Engineering, UNIST, ³Beijing Computational Science Research Center, ⁴Department of Materials Science and Engineering, Seoul National University</p>
WP-045	<p>Electro-Optical Switching Behavior of VO₂(M) Thin Films for Integrated Photonic Modulators</p> <p>Namhoon Kim^{1,2}, Jaehyeon Gyeong¹, Heonjin Choi², and Donghee Park¹</p> <p>¹Center for Quantum technology, Post-Silicon Semiconductor Institute, KIST, ²Department of Materials Science and Engineering, Yonsei University</p>



WP-046	<p>Understanding Rapid Growth Mechanism of MOCVD-Grown Wafer-Scale MoS₂ under BEOL Compatible Temperature</p> <p>Taehyeon Kim^{1,2,3}, Jaemin Myoung^{1,2,3}, Taesung Kim⁴, and Jihun Mun¹</p> <p>¹Strategic Technology Research Institute, KRISS, ²SKKU Advanced Institute of Nanotechnology (SAINT), Sungkyunkwan University, ³Department of Nano Science and Technology, Sungkyunkwan University, ⁴School of Mechanical Engineering, Sungkyunkwan University</p>
WP-047	<p>Epitaxial Synthesis of Highly Crystalline RuO₂ Thin Films via RF-Magnetron Sputtering</p> <p>Min-Seok Kim^{1,2}, Jun-Hyeong Park^{1,2}, Dong Hyun Lim^{1,3}, Jun Min Suh^{2,4}, Ho Won Jang², Seung-Hyub Baek^{1,5}, and Tae Heon Kim^{1,5}</p> <p>¹Electronic and Hybrid Materials Research Center, KIST, ²Department of Materials Science and Engineering, Research Institute of Advanced Materials, Seoul National University, ³Department of Semiconductor Engineering, Seoul National University of Science & Technology, ⁴School of Transdisciplinary Innovations, Seoul National University, ⁵Division of Nanoscience and Technology, KIST School, University of Science and Technology</p>
WP-048	<p>Temperature-Dependent Phase Transition in WS₂ for Reinforcing Band-to-Band Tunneling and Photoreactive Random Access Memory Application</p> <p>Hyun Woo Shim¹, Gun Hoo Woo², Jin Il Cho², and Tae Sung Kim¹</p> <p>¹School of Semiconductor Convergence Engineering, Sungkyunkwan University, ²Memory Division, Samsung Electronics Co., Ltd.</p>
WP-049	<p>The Preparation of Trans-2-Fluoro-3-(Trifluoromethyl)oxirane for Plasma-Based Dry Etching</p> <p>김성미^{1,2}, 홍유진¹, 오명석¹, 채희엽², 장봉준¹</p> <p>¹한국화학연구원 계면재료 화학공정 연구센터, ²성균관대학교 화학공학과</p>
WP-050	<p>Anion-Controlled Transition Metal-Based Catalysts for Sustainable Chemical Processes</p> <p>So Hyeon Kwon, Jaeyong Lee, Hwiyoung Kwon, Daeun Kim, Yubin Choi, and Haeri Lee</p> <p>Department of Chemistry, Hannam University</p>



WP-051	<p>Role of Intermediates in Salt-Assisted CVD Growth of Molybdenum Disulfide</p> <p>Chanmin Park¹, YongJu Kim¹, Jaewoo Ku¹, Hyeonryul Lee², Sooncheol Kwon³, and Minsu Kim¹</p> <p>¹Department of Advanced Materials Engineering, Kyonggi University, ²Department of Advanced Battery Convergence Engineering, Dongguk University, ³Department of Energy and Materials Engineering, Dongguk University</p>
WP-052	<p>Thickness-Driven Evolution of Crystallographic Symmetry and the Resulting Domain Twinning in Epitaxial Perovskite Oxide (001) Thin Films</p> <p>Dong-Hun Han^{1,2}, Jaebaek Ju^{1,3}, Donghyeon Lim^{1,4}, Ho Won Jang^{2,5}, Tae Heon Kim^{1,6}, and Seung-Hyub Baek^{1,6}</p> <p>¹Electronic and Hybrid Materials Research Center, KIST, ²Department of Materials Science and Engineering, Research Institute of Advanced Materials, Seoul National University, ³Department of Materials Science and Engineering, Korea University, ⁴Department of Semiconductor Engineering, Seoul National University of Science & Technology, ⁵Advanced Institute of Convergence Technology, Seoul National University, ⁶Division of Nanoscience and Technology, KIST School, University of Science and Technology</p>
WP-053	<p>Thermal Conductivity Measurements of Nickel-Based Alloy Thin Films with Different Alloy Compositions</p> <p>Minkyu Je, Ajin Jo, Taeyeon Kim, Chan Kim, Jihyun Kim, Dongwoo Lee, and Jungwan Cho</p> <p>School of Mechanical Engineering, Sungkyunkwan University</p>
WP-054	<p>Thermal Characterization of Sputtered HfO₂ Thin Films on Si Using Frequency-Domain Thermoreflectance</p> <p>Hyeokje Kim, Euimin Cheong, Taeyeon Kim, Jihyun Kim, Dongwoo Lee, and Jungwan Cho</p> <p>School of Mechanical Engineering, Sungkyunkwan University</p>



WP-055	<p>Bandgap and Work Function in Semiconducting HfSe₂ Films</p> <p>Mincheol Kim^{1,2,3}, Tae Gyu Rhee^{1,3}, Young Rok Khim¹, Yeong Gwang Khim^{1,2}, Young Hoon Khim¹, Dang Nguyen Hoang⁴, Nguyen Huu Lam⁴, Ganbat Duvjir⁴, Jungdae Kim⁴, Rovi Angelo Belaya Villaos⁵, Feng-Chuan Chuang⁵, and Young Jun Chang¹</p> <p>¹Department of Physics, University of Seoul, ²Department of Smart Cities, University of Seoul, ³KIST, ⁴Department of Physics and Energy Harvest-Storage Research Center, University of Ulsan, ⁵Center for Theoretical and Computational Physics, National Sun Yat-sen University</p>
WP-056	<p>오비탈 전류의 분극제어를 통한 무자기장 수직자화 스위칭</p> <p>정건우¹, 윤성중¹, 전홍원¹, 우다은¹, 조흥래¹, 김우진¹, 양희창², 김혜진³, 이원익², 박민서², 전세윤³, 최현경², 김종윤², 김동현³, 엄기태¹, 이수길¹</p> <p>¹가천대학교 반도체공학과, ²가천대학교 반도체전자공학부 차세대반도체공학전공, ³가천대학교 반도체전자공학부 전자공학전공</p>
WP-057	<p>Growth and Characterization of Two-Dimensional Molybdenum Disulfide by Using Metal Organic Chemical Vapor Deposition</p> <p>Jeongseo Moon^{1,2}, Won Young Jang³, Kyung Rim Kang⁴, Min-jae Lee³, Hong Seok Ko⁴, Seong Bin You⁵, Kang Bok Ko², Bo-In Park^{1,2,3}, Chel-jong Choi^{1,2,3}, and Keun Heo^{1,2,3}</p> <p>¹School of Semiconductor and Chemical Engineering, Jeonbuk National University, ²Semiconductor Physics Research Center, Jeonbuk National University, ³Department of Semiconductor Science and Technology, Jeonbuk National University, ⁴Department of Electronic Engineering, Jeonbuk National University, ⁵Division of Advanced Materials Engineering, Jeonbuk National University</p>
WP-058	<p>Titanium Carbide MXene Based Composite for Multi-Directional Heat Spreader</p> <p>Seoyeon Choi¹, Young Ho Jin¹, Yeongcheol Park², Jae Hun Seol², and Soon-Yong Kwon²</p> <p>¹Department of Materials Science and Engineering and Graduate School of Semiconductor Materials and Devices Engineering, UNIST, ²Department of Mechanical Engineering, GIST</p>



WP-059	<p>Precursor-Driven Morphological Control of MXenes for High-Performance EMI Shielding and Energy Storage</p> <p>Jaeeun Park¹, Ju-Hyoung Han¹, Yujin Chae¹, Mincheal Kim², Juwon Han¹, Younggeun Jang^{1,3}, Young Ho Jin¹, Jaewon Wang¹, Zonghoon Lee^{1,3}, EunMi Choi², and Soon-Yong Kwon^{1,4}</p> <p>¹Department of Materials Science and Engineering, UNIST, ²Department of Electrical Engineering, UNIST, ³Center for Multidimensional Carbon Materials, IBS, ⁴Graduate School of Semiconductor Materials and Devices Engineering, UNIST</p>
WP-060	<p>WS₂-MoSe₂ Heterostructures Grown by Two-Step Metal-Organic Chemical Vapor Deposition</p> <p>Chaehui Lim^{1,2}, Wonchan Lee^{1,2}, Yunjung Cho^{1,2}, Seohee Park^{2,3}, and Seunguk Song^{1,2}</p> <p>¹Department of Energy Science, Sungkyunkwan University, ²Center for 2D Quantum Heterostructures, IBS, Sungkyunkwan University, ³Department of Chemistry, Sungkyunkwan University</p>
WP-061	<p>Defect-Engineered Epitaxial Growth of WS₂ Monolayer for 2D Optoelectronics</p> <p>Yunjung Cho^{1,2}, Wonchan Lee^{1,2}, Seohee Park^{2,3}, and Seunguk Song^{1,2}</p> <p>¹Department of Energy Science, Sungkyunkwan University, ²Center for 2D Quantum Heterostructures, IBS, Sungkyunkwan University, ³Department of Chemistry, Sungkyunkwan University</p>
WP-062	<p>Understanding the First-Firing Mechanism in Ge-Te Based Binary Ovonic Threshold Switches through Atomic-Scale Analysis and First-Principles Calculations</p> <p>Young-Min Kim^{1,2}, Siwon Park^{1,2}, Sangyeop Kim^{1,2}, and Jong-Souk Yeo¹</p> <p>¹School of Integrated Technology, College of Computing, Yonsei University, ²BK21 Graduate Program in Intelligent Semiconductor Technology</p>
WP-063	<p>집속 이온빔 패터닝을 통한 InGaN/GaN 양자점의 선택적 영역 성장</p> <p>김바울, 조용훈</p> <p>한국과학기술원 물리학과</p>



WP-064	<p>Investigation of Multiferroic ε-Ga_{2-x}Fe_xO₃ Thin Films Grown by Mist CVD</p> <p>Young Soo Hwang, Ha Young Kang, Jae Heon Jung, and Roy Byung Kyu Chung</p> <p>School of Materials Science and Engineering, Kyungpook National University</p>
WP-065	<p>Carbon Coated-Nitride MAXene/MoS₂ Heterogeneous Catalyst for Hydrogen Evolution Reaction</p> <p>Yujin Chae¹, Yeoseon Sim¹, Shi-Hyun Seok¹, Jaeeun Park¹, Ju-Hyoung Han¹, Young Ho Jin¹, and Soon-Yong Kwon^{1,2}</p> <p>¹Department of Materials Science and Engineering, UNIST, ²Graduate School of Semiconductor Materials and Devices Engineering, UNIST</p>
WP-066	<p>Spatially Confined Vapor-Phase Growth of MoTe₂-WS₂ Lateral Heterostructure</p> <p>Inbae Song^{1,2}, Yunjung Cho^{1,2}, Kyungwu Kwon^{1,2}, Wonchan Lee^{1,2}, and Seunguk Song^{1,2}</p> <p>¹Department of Energy Science, Sungkyunkwan University, ²Center for 2D Quantum Heterostructures, IBS, Sungkyunkwan University</p>
WP-067	<p>In Situ Observation of a Confined Nucleation and Growth of Bi Particles in δ-Bi₂O₃ Nanosheets</p> <p>Hyeon Jin Choi, Yun Jae Jeong, Jin Young Kim, Chan Hee Hwang, and Young Heon Kim</p> <p>Graduate School of Analytical Science and Technology, Chungnam National University</p>
WP-068	<p>Ce-Induced Lattice Expansion of BaZrO₃ for Advanced Substrate</p> <p>Biprojit Sana, Dong Whee Kim, Hei Woong Lee, and Yoon Seok Oh</p> <p>Department of Physics, UNIST</p>
WP-069	<p>Quantitative Analysis of Hydrogen in H_xVO₂</p> <p>Byungho Lee^{1,2}, Jinwook Lee^{1,2}, and Woo Jin Kim^{1,2}</p> <p>¹Department of Materials Science and Engineering, Pusan National University, ²Institute of Materials Technology, Pusan National University</p>
WP-070	<p>One-Step SiO₂ Coating for Reliable Insulation in High-Density Probe</p> <p>Minsoo Jang and Doowon Lee</p> <p>Division of Electrical, Electronic and Control Engineering, Kongju National University</p>



제 33회 한국반도체학술대회

The 33rd Korean Conference on Semiconductors

2026년 1월 27일(화)~30일(금) | 강원도 하이원리조트 그랜드호텔(컨벤션타워)

A Paradigm Shift in Semiconductors for AI Era

WP-071	<p>Epitaxial Growth of Twin-Free Orthorhombic SrCuO₂ Thin Films</p> <p>Jiwon Lee^{1,2}, Jaewoo Lee^{1,2}, Hyungmok Lee^{1,2}, and Woo Jin Kim^{1,2}</p> <p>¹Department of Materials Science and Engineering, Pusan National University, ²Institute of Materials Technology, Pusan National University</p>
WP-072	<p>Fluorine-Doped N-Type α-Ga₂O₃ and Its Phase Stability</p> <p>Choi Yoonho and Roy Byung Kyu Chung</p> <p>Department of Materials Science & Engineering, Kyungpook National University</p>
WP-073	<p>Electrical Properties of AlN</p> <p>Do Hyun Kim¹, Ji Soo Jang², Nimphy Sarkar¹, Da Hyung Kim¹, Seon Namgung¹, Taenam Kwon¹, Kunook Chung¹, Se Young Park³, Seung Hyub Baek², Tae Heon Kim², and Yoon Seok Oh¹</p> <p>¹UNIST, ²KIST, ³Department of Physics, Soongsil University</p>
WP-074	<p>TCAD Simulation Based Modeling of Short-Wave Infrared PbS CQD Photodiode</p> <p>Eunsoo Lim¹, Junghun Kim², and Jiwon Lee^{1,2}</p> <p>¹Department of Semiconductor Engineering, POSTECH, ²Graduate School of Semiconductor Technology, POSTECH</p>



2026-01-28(수), 10:00-19:00

(공식발표시간: 17:30-19:00)

ZONE2-2 (5층, 로비)

[WP] 포스터세션

L. Analog Design 분과

WP-171	<p>A PVT-Compensated LDO with a Process-Calibration BGR and a Temperature-Coefficient Cancelled BMR</p> <p>황중환, 류지환, 김민우, 김윤수, 염인선, 최명현, 양병도</p> <p>충북대학교 전자정보대학 반도체공학부</p>
WP-172	<p>Wide-Range, Fast-Locking Referenceless CDR based on BFSM</p> <p>Jinwoo Hong, Jongmin Park, and Jinwook Burm</p> <p>Department of Electronic Engineering, Sogang University</p>
WP-173	<p>A 12-bit Column-Parallel Two-Step TDC-Assisted SAR ADC for CIS</p> <p>Jongmin Kim, Wooseok Jung, and Jinwook Burm</p> <p>Department of Electronic Engineering, Sogang University</p>
WP-174	<p>All-Digital CDR with Fast Locking and Improved PI Linearity Using an Injection-Locked Ring Oscillator</p> <p>Jimin Kim, Taeuk Kim, and Jinwook Burm</p> <p>Department of Electronic Engineering, Sogang University</p>
WP-175	<p>A High PSR, Fast Transient Response Dual-Pass Transistor Capacitor-Less LDO for X-Ray Detector Applications</p> <p>Hyeonjae Yoo¹, Seungpyo Oh², Dooho Kim¹, Kang Heo¹, Kyunghun Yoon¹, and Jooyeol Rhee²</p> <p>¹Advanced Technology R&D Center, Viewworks Co., ²College of Semiconductor, Gachon University</p>
WP-176	<p>임베디드 플래시 구동을 위한 복구시간 감지 기반 레귤레이터 내장형 차지 펌프</p> <p>김준서^{1,4}, 김정남^{2,4}, 김윤^{2,4,5}, 구민석^{3,4,5}</p> <p>¹서울시립대학교 지능형반도체학과, ²서울시립대학교 전자전기컴퓨터공학부, ³서울시립대학교 첨단융합학부, ⁴서울시립대학교 반도체 연구센터(UOS-FAB), ⁵주식회사 IM전자</p>



WP-177	A Low-Power RF-DC Converter Using an Adaptive Architecture to Achieve a 43-dB Wide-Input-Range for RF Energy Harvesting Yeji Han and Ickjin Kwon School of Electrical and Computer Engineering, Ajou University
WP-178	Comparator Offset Calibration for Single-Channel Speculative Loop-Unrolled SAR ADC in 28-nm CMOS Dong-Un Jin and Min-Seong Choo Department of Electronic Engineering, Hanyang University
WP-179	Power and Area Efficient Time-Domain ADC Youngwoo Kwon and Hyungil Chae Konkuk University
WP-180	A C-CI SAR ADC with Pulse-Gating Charge-Injection Cell Junmin Park and Hyungil Chae Konkuk University
WP-181	A High-Resolution Supply-Noise-Insensitive Linear Digital-to-Time Converter for Low-Noise Fractional Dividers Yuna Hwang ^{1,2} and Woo-Seok Choi ^{1,2} ¹ Department of Electrical and Computer Engineering, Seoul National University, ² Inter-university Semiconductor Research Center, Seoul National University
WP-182	A Study on Extremely Low-Power Design and Operation for High-Performance Digital Pixel Sensor Jaehun Jeong, Sanggwon Lee, Yong-Suk Choi, Yeongseok Shim, Gihwan Cho, Youna Lee, Bumjun Kim, Su-Hyun Han, Heesung Shim, Min-Woong Seo, Jae-kyu Lee, and Jonghyun Go Semiconductor R&D Center, Samsung Electronics Co., Ltd.
WP-183	아날로그 부궤환을 이용하여 주변광 간섭을 상쇄하는 PPG 아날로그 수신단 증폭기 Minji Kim and Ji-Yong Um Department of Medical IT Convergence Engineering, Kumoh National Institute of Technology



WP-184	<p>A High-Power-Supply-Rejection Capless Low-Dropout Regulator with Extended Bandwidth</p> <p>Min-Seo Kim, You-Chan Kim, Hui-Won Jeong, Joon-Ho Im, and Byong-Deok Cho</p> <p>Department of Electronic Engineering, Hanyang University</p>
WP-185	<p>Ultra-Low Quiescent Current OCL-LDO With Fast-Transient Response</p> <p>Dong-Wook Jeong and Ickjin Kwon</p> <p>Department of Electrical and Computer Engineering, Ajou University</p>
WP-186	<p>보조 패스 트랜지스터의 방전 전류 및 다이오드 커넥티드 MOS 이용한 빠른 과도응답을 가지는 Ultra-Low-Power OCL-LDO 레귤레이터 설계</p> <p>김주훈, 권익진</p> <p>아주대학교 전자공학과</p>
WP-187	<p>12-Bit, 640MSps TI-SAR ADC With Clock Distribution Layout Technique for WiFi-6 Application</p> <p>안상준, 김선우, 황인성, 여중기, 정보근, 백동현, 김영진</p> <p>한국항공대학교 Nanowave-Integrated Circuit and System Lab</p>
WP-189	<p>전력반도체 게이트 구동 드라이버의 Isolation을 위한 구동 환경 변화에 둔감한 신호 변조 회로</p> <p>김남현^{1,2}, 심민섭², 김기현¹, 송기남¹</p> <p>¹한국전기연구원 파워SoC연구센터, ²경상국립대학교</p>
WP-190	<p>Radiation-Hardened Logic Gate Design Methodology Considering NMOS Dimension Variation under TID Effects</p> <p>Serin Lee, Kihyun Kim, and Kyoungcho Lee</p> <p>KERI</p>



2026-01-28(수), 10:00-19:00

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ZONE2-2 (5층, 로비)

[WP] 포스터세션

N. VLSI CAD 분과

WP-200	High-Frequency Clock Generator Design based on Logic Synthesis for Cross-Process Portability Sooah Choi, Jihoon Park, and Jae-Joon Kim Department of Electrical and Computer Engineering, Seoul National University
WP-201	A16K: 1.6nm NSFET, FSFET, and CFET Technology Libraries for Chip-Level VLSI Prediction Hwiryong Kim ¹ , Hanmok Park ¹ , Mingyun Sun ² , Yongjin Kwon ² , Jiyeon Jung ² , Gahyeon Kim ² , Gyengjin Kim ² , Sunmean Kim ¹ , and Taigon Song ² ¹ School of Electronics and Electrical Engineering, Kyungpook National University, ² School of Electronics Engineering, Kyungpook National University
WP-202	In-Cell Routability Prediction for Complementary FET Standard Cell Transistor Placement Seo Yeong Mun ¹ and Suwan Kim ² ¹ Department of Convergent Biotechnology And Advanced Materials Science, Kyung Hee University, ² Department of Electronic Engineering, Kyung Hee University
WP-203	A Perceptron Hybrid Branch Predictor for Ternary Pipelined Architectures Seonghoon Kim, Hanmok Park, Sunmean Kim, and Taigon Song School of Electronic and Electrical Engineering, Kyungpook National University
WP-204	A Hardware-Level Framework for Training and Inference of Capacitive Computing-in-Memory Architecture Changhyeon Park ^{1,2} and Woo Young Choi ^{1,2} ¹ Department Electrical and Computer Engineering, Seoul National University, ² Inter-university Semiconductor Research Center, Seoul National University



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A Paradigm Shift in Semiconductors for AI Era

WP-205	Area and Energy-Efficient Architecture for p-Bit Digital Ising Machine Jin Su Kim, Jun Hee Lee, Ji Hoon Park, and Jae Joon Kim Seoul National University
WP-206	An RTL-Based General Synthesis Methodology for Device-Independent Ternary Logic Circuits Hanmok Park, Seonghoon Kim, and Taigon Song School of Electronics and Electrical Engineering, Kyungpook National University
WP-207	온도를 고려한 정적 타이밍 분석과 임계 경로 변화 분석 조혜양, 박영훈, 정준서, 김강훈, 김현수, 박성범, 김주호 서강대학교 컴퓨터공학과
WP-208	SRAM 기반 인메모리 컴퓨팅에서 전력 효율적인 Adder Tree를 위한 아키텍처 및 트랜지스터 수준 설계의 학습 기반 공동 최적화 고다훈 ¹ , 송민근 ¹ , 이준서 ¹ , 우재현 ¹ , 조형원 ¹ , Aigany Zhalinova ¹ , 강성원 ² , 강지수 ² , 김태민 ² , 김태우 ² , 정한울 ¹ ¹ 연세대학교 전기전자공학과, ² Department of Electronic Engineering, Kwangwoon University
WP-209	머신러닝 기반 설계 최적화를 이용한 에너지 효율적 SRAM 기반 메모리 내 연산 회로 박세준 ¹ , 유두현 ¹ , 고동현 ¹ , 정우석 ¹ , 김태성 ¹ , 한창용 ¹ , 박관우 ² , 백재승 ² , 장이준 ² , 손승원 ² , 정한울 ¹ ¹ 연세대학교 전기전자공학과, ² Department of Electronic Engineering, Kwangwoon University
WP-210	Post-Scaler: Architecture Support for True FP-INT GEMM Jihyun Moon ^{1,3} and Joon-Sung Yang ^{1,2,3} ¹ Department of Systems Semiconductor Engineering, Yonsei University, ² Department of Electrical and Electronic Engineering, Yonsei University, ³ BK21 Graduate Program in Intelligent Semiconductor Technology, Yonsei University



WP-211	<p>Ancilla-Aware Tiled Architecture for Efficient Surface Code Communication in Fault-Tolerant Quantum Computing</p> <p>Youngjung Kang¹ and Joon-Sung Yang^{1,2,3}</p> <p>¹Department of System Semiconductor Engineering, Yonsei University, ²Department of Electrical and Electronic Engineering, Yonsei University, ³BK21 Graduate Program in Intelligent Semiconductor Technology, Yonsei University</p>
WP-212	<p>DNN Accelerator Exploiting Slice-Level Sparsity with Bit-Slice Architecture</p> <p>Insu Choi¹ and Joon-Sung Yang^{1,2,3}</p> <p>¹Department of Electrical and Electronic Engineering, Yonsei University, ²Department of System Semiconductor Engineering, Yonsei University, ³BK21 Graduate Program in Intelligent Semiconductor Technology, Yonsei University</p>
WP-213	<p>자기 지도 학습 기반 테스트 포인트 삽입</p> <p>박태민¹, 양준성^{1,2,3}</p> <p>¹연세대학교 전기전자공학과, ²연세대학교 시스템반도체공학과, ³연세대학교 지능형반도체IT융합전공</p>
WP-214	<p>Automated Layout Optimization for Planar MOSFETs Considering Local Layout Effects (LLE)</p> <p>Ji-hye Yoo¹, Gaon Lee², June-yeop Lee¹, and Jong-wook Jeon¹</p> <p>¹Department of Electrical and Computer Engineering, Sungkyunkwan University, ²Department of Display Engineering, Sungkyunkwan University</p>
WP-215	<p>Logic Optimization via Reinforcement Learning-Guided Gate Transformation</p> <p>Donghyuk Lee, Hyunmin Jo, and Heechun Park</p> <p>UNIST</p>
WP-216	<p>Robust Fusion-Based Acceleration of Attention Training on Edge Hardware</p> <p>Dowon Kwon, Joonseok Kim, Jonghyeon Nam, and Seokhyeong Kang</p> <p>Graduate School of Semiconductor Technology, POSTECH</p>
WP-217	<p>LLM-Based Code Augmentation for Generating PPA-Diverse RTL Designs</p> <p>Yeonwoo Shim¹, Sunsang Gwon², and Seokhyeong Kang²</p> <p>¹Department of Semiconductor Engineering, POSTECH, ²Department of Electrical Engineering, POSTECH</p>



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A Paradigm Shift in Semiconductors for AI Era

WP-218	<p>FPGA 구현을 위한 경량 인공지능 기반 ADC 실시간 보정 구조 설계</p> <p>강륜¹, 김건¹, 김동영¹, 김수연¹, 김신욱¹, 박제원¹, 김소원¹, 임채혁¹, 서현아¹, 윤정현¹, 이주원¹, 이해린¹, 최우진², 김어진², 정민우², 이명진¹</p> <p>¹전남대학교 지능전자컴퓨터공학과, ²전남대학교 전자컴퓨터공학부</p>
WP-219	<p>고신뢰도 IR Drop 예측을 위한 물리 기반 후처리 전류 인식 보정 및 이방성 필터링</p> <p>고운</p> <p>서강대학교 컴퓨터공학과</p>



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ZONE3 (6층, 로비)

[WP] 포스터세션

B. Patterning (Lithography & Etch Technology) 분과

WP-001	<p>저 지구온난화지수 HFE-347 이성질체를 이용한 SiO₂ Contact Hole 식각</p> <p>김민욱^{1,2}, 김창구^{1,2}</p> <p>¹Department of Chemical Engineering, Ajou University, ²Department of Energy Systems Research, Ajou University</p>
WP-002	<p>지구온난화지수가 낮은 Fluorinated Alcohol 플라즈마를 이용한 SiO₂ 식각</p> <p>김준영^{1,2}, 김창구^{1,2}</p> <p>¹Department of Chemical Engineering, Ajou University, ²Department of Energy Systems Research, Ajou University</p>
WP-003	<p>Forward Metal-Assisted Chemical Etching for Self-Aligned Recess-Gate β-Ga₂O₃ MESFETs</p> <p>김지호^{1,2}, 최웅¹, 김지현¹</p> <p>¹서울대학교 화학생명공학부, ²삼성전자 DS 메모리사업부</p>
WP-004	<p>Temperature-Dependent HF Physisorption Etching Mechanisms of SiO₂ and SiN in NF₃/H₂ Plasma</p> <p>Jungjae Yoo, Taemin Kim, Youngmin Sunwoo, Paul Seo, Hongsik Jeong, and Byungjo Kim</p> <p>Graduate School of Semiconductor Materials and Devices Engineering, UNIST</p>
WP-005	<p>광-보조 습식 세정을 통한 High-NA EUV 마스크 상의 Sn 오염 입자 제거 효율 향상</p> <p>최웅¹, 박제환¹, 김문경², 김지현¹</p> <p>¹서울대학교 화학생명공학부, ²삼성전자 파운드리사업부</p>



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WP-006	<p>Nanoporous MoS₂ Bio-FET for Artificial Olfaction with Edge-Dominant VOC Sensing</p> <p>Subin Lim¹ and Sunkook Kim²</p> <p>¹Department of Display Engineering, Sungkyunkwan University, ²School of Advanced Materials Science and Engineering, Sungkyunkwan University</p>
WP-007	<p>고종횡비 구조 내 이온-표면 상호작용의 물리적 메커니즘 규명을 위한 분자동역학-AI 융합 시뮬레이션 프레임워크</p> <p>선우영민, 이도훈, 홍준표, 김병조</p> <p>울산과학기술원 반도체 소재·부품 대학원</p>
WP-008	<p>Explainable AI 기반 NF₃/H₂ 플라즈마의 SiO₂ 및 SiN 저온 식각 메커니즘 분석</p> <p>서바울, 선우영민, 김태민, 유정재, 정홍식, 김병조</p> <p>울산과학기술원 반도체 소재·부품 대학원</p>
WP-009	<p>Revisiting the Role of Carboxylates in Organotin Carboxylate EUV Resists</p> <p>Hyeok Yun, Hayun Kim, Wonchul Kee, and Hyun-Dam Jeong</p> <p>Department of Chemistry, Chonnam National University</p>
WP-010	<p>Synthesis and Evaluation of Function-Integrated Inorganic Molecular Resists for EUV Lithography</p> <p>Gahyun Lee, Pronab Kumar Singha, Seung-yong Baek, Hyeok Yun, and Hyun-Dam Jeong</p> <p>Department of Chemistry, Chonnam National University</p>
WP-011	<p>High-Sensitivity Negative-Tone Tin-Oxo Molecular Resist for EUV Lithography</p> <p>Soyeong Heo, Wonchul Kee, and Hyun-Dam Jeong</p> <p>Department of Chemistry, Chonnam National University</p>
WP-012	<p>Surface Characterization of Siloxane Molecular Resists: Understanding Chemical Contrast for Next-Generation Lithography</p> <p>Jiyoung Bang, Hyeok Yun, Wonchul Kee, Donghwan Kim, and Hyun-Dam Jeong</p> <p>Department of Chemistry, Chonam National University</p>



WP-013	<p>Molecular Tin-Orthosilicates: Synthesis, Characterization, and Electron-Beam Lithography Application for EUV Resists</p> <p>Jiyoung Bang¹, Hyeok Yun¹, Soyoung Heo¹, Seung Hwan Kang², Yusun Won², Hyun Tae Jung², and Hyun-Dam Jeong¹</p> <p>¹Department of Chemistry, Chonnam National University, ²JSI Silicone Inc.</p>
WP-014	<p>Synthesis and Structural Characterization of a Monomeric Inorganic Resist for EUV Lithography</p> <p>Wonchul Kee¹, Hayun Kim¹, Soyeong Heo¹, Jiyoung Bang¹, Hyun-Sung Yoon¹, Seungyong Baek¹, Gahyun Lee¹, Hyeok Yun¹, Eun-Seok Choe², Jung-Hyung Kim², and Hyun-Dam Jeong¹</p> <p>¹Department of Chemistry, Chonnam National University, ²KRISS</p>
WP-015	<p>Radical Generation and Fragmentation Mechanisms of Decomposition Products from C₃F₈O and C₄F₈O</p> <p>Minji Kim and Sangheon Lee</p> <p>Chemical Engineering and Materials Science, Ewha Woman's University</p>
WP-016	<p>Molecular Design and Synthesis of Extreme UV Photoresists Incorporating Unsaturated Carbon Units and Tin Atoms</p> <p>Gayoung Kim¹, Junsik Kim¹, Sung-Wook Hwang¹, Dain Park¹, Yejin Ku¹, Jinseok Lee¹, Seokmin Kang¹, Jiho Kim³, Geonwha Kim³, Sangsul Lee³, and Jin-Kyun Lee^{1,2}</p> <p>¹Program in Environment and Polymer Engineering, Inha University, ²Department of Polymer Science and Engineering, Inha University, ³Pohang Accelerator Laboratory, POSTECH</p>
WP-017	<p>Atomic Layer Etching of SiO₂ and SiN_x Using Combined Remote and Direct Plasma Processes</p> <p>Sung Hyun Lim, So Won Kim, and Hee Chul Lee</p> <p>Department of Advanced Materials Engineering, Tech University of Korea</p>
WP-018	<p>저온전자온도 플라즈마를 이용한 EUV 포토레지스트 건식 현상 공정 기술</p> <p>김지원^{1,4}, 석지후^{1,4}, 윤광섭^{1,3}, 이태호⁴, 정진욱^{2,4}, 안진호^{1,4}</p> <p>¹한양대학교 신소재공학과, ²한양대학교 전기공학과, ³삼성전자 반도체 연구소, ⁴극한스케일·극한물성-이종집적 한계극복 반도체 기술 연구센터</p>



WP-019	<p>Reaction-Condition Optimization for Impurity Suppression and Purification of Tin-Oxo Cluster CNU-TOC-01 (4C-C)</p> <p>Seung-Yong Baek, Cheol-Ho Jo, Seung-Hoon Park, and Hyun-Dam Jeong Department of Chemistry, Chonnam National University</p>
WP-020	<p>Formulation-Process Optimization Guided by Electron-Beam Evaluation for EUV Resists</p> <p>Seung-Yong Baek, Wonchul Kee, and Hyun-Dam Jeong Department of Chemistry, Chonnam National University</p>
WP-021	<p>Efficient Prediction of Wafer-Radius Ion Energy and Angular Distributions with Machine Learning for Plasma Etching</p> <p>Wan-gyu Gwak¹, Kyeong-Bin Kim², Jongchan Park³, Chan-Young Choi⁴, and Eun-ho Lee^{1,2,3}</p> <p>¹Department of Smart Fab. Technology, Sungkyunkwan University, ²Department of Mechanical Engineering, Sungkyunkwan University, ³Department of Intelligent Robotics, Sungkyunkwan University, ⁴SEMES Co., Ltd.</p>
WP-022	<p>Organic-Inorganic Hybrid Positive-Tone Photoresist via MLD for EUV Lithography</p> <p>Junseong Hur¹, Jaehyuk Lee², Hyeonseok Ji², Nguyen Quang Khanh², Chaerim Kim², Soojin Park¹, Tran Cuong Dai², Heeseo Kim², and Myung Mo Sung²</p> <p>¹Department of Semiconductor Engineering, Hanyang University, ²Department of Chemistry, Hanyang University</p>
WP-023	<p>Vertical Molecular Wire Structured Hybrid Multilayer Photoresist for Extreme Ultraviolet Lithography Using Molecular Layer Deposition</p> <p>Taeon Kim¹, Heemin Kang², Hyeonseok Ji¹, Jaehyuk Lee¹, Chaerim Kim¹, and Myung Mo Sung¹</p> <p>¹Department of Chemistry, Hanyang University, ²Department of Semiconductor Engineering, Hanyang University</p>
WP-024	<p>DFT를 이용한 초기 CF_x 라디칼 흡착을 통한 비정질 Si₃N₄ 표면에서의 플루오로카본 필름 연구</p> <p>조미현, 이상현 이화여자대학교 화공신소재공학과</p>



WP-025	<p>Development of Fluorinated Protective Layer and Its Integration with Water-Transfer Photolithography for Organic Semiconductor Patterning</p> <p>김서연¹, 김가영¹, 권유정¹, 엄준호³, 최재학^{3,4}, 이진균^{1,2}</p> <p>¹Program in Environment and Polymer Engineering, Inha University, ²Department of Polymer Science and Engineering, Inha University, ³Department of Materials Science and Engineering, Chungnam National University, ⁴Department of Polymer Science and Engineering, Chungnam National University</p>
WP-026	<p>Multiscale Patterning of Single-Crystal C8-BTBT Enabled by a PDMS Solvent-Diffusion Process</p> <p>Seeun Kwon, Sangtae Lee, Dongjun Lee, Bumseo Park, and Insung Bae Hannam University</p>
WP-027	<p>Development of a Multi-Sensor-Based Defect Classification and Endpoint Prediction Model for Semiconductor Metal Etching Process Using Machine Learning</p> <p>Minseo Kim¹, Suyeon Kim², Heejin Moon³, and Dagyeong Hong⁴</p> <p>¹Dong-Eui University, ²Pusan National University, ³Kyungpook National University, ⁴Seoul National University of Science & Technology</p>
WP-028	<p>Plasma-Enhanced Atomic Layer Etching for Fine Line Patterns of Next-Generation Interconnect Materials</p> <p>Daehan Won^{1,2}, Harin Song^{1,2}, Hongju Yang^{1,2}, Hojin Chung^{1,2}, Chee Won Chung^{1,2}, and In-Hwan Baek^{1,2}</p> <p>¹Department of Chemical Engineering, Inha University, ²Program in Semiconductor Convergence, Inha University</p>
WP-029	<p>Reaction Mechanism of Zirconium Oxide Atomic Layer Etching: An In vacuo XPS Study</p> <p>Mi-Soo Kim¹, Eunju Ham¹, Sejeong Jo^{1,2}, Hyun-jeong Yoo^{1,2}, Hye-Lee Kim^{1,2}, Youn Seoung Lee³, Sun-Jae Kim^{1,2}, and Won-Jun Lee^{1,2}</p> <p>¹Department of Nanotechnology and Advanced Materials Engineering, Sejong University, ²Metal-organic Compounds Materials Research Center, Sejong University</p>



	University, ³ Department of Information and Communication Engineering, Hanbat National University
WP-030	Atomic Layer Etching of Cobalt Thin Films via Surface Fluorination and Low-Energy Ar⁺ Ion Activation Yeh Been Im ¹ , Young Don Kim ² , Hyeon Jun Cho ³ , Chin Wook Chung ^{2,3} , and Changhwan Choi ^{1,2} ¹ Division of Materials Science and Engineering, Hanyang University, ² Department of Semiconductor Engineering, Hanyang University, ³ Department of Electrical Engineering, Hanyang University
WP-031	H₂O and O₂ Additive Effects on Cryogenic Etching of SiO₂ and Si₃N₄ in CF₄/Ar Plasmas under Self-Bias Conditions Kangwoo Lee ¹ , Haegeon Jung ^{2,3} , Hakseung Lee ^{2,3} , Daeun Hong ¹ , Minsung Jeon ⁴ , and Heeyeop Chae ^{1,4} ¹ School of Chemical Engineering, Sungkyunkwan University, ² Department of Semiconductor and Display Engineering, Sungkyunkwan University, ³ Samsung Institute of Technology, Samsung Electronics Co., Ltd., ⁴ Department of Semiconductor Convergence Engineering, Sungkyunkwan University
WP-032	Plasma Atomic Layer Etching of Molybdenum for Low-Damage and Precisely Controllable Etch Process Donguk Kim ¹ , Hyunjin Yim ² , Yehbeen Im ² , Youngseo Na ¹ , Kangbaek Seo ¹ , Seungchae Lee ² , Kanghyeok Lee ¹ , Sangtae Park ² , and Changhwan Choi ^{1,2} ¹ Department of Semiconductor Engineering, Hanyang University, ² Division of Materials Science and Engineering, Hanyang
WP-033	Atomic-Scale Smoothing of Cobalt Thin Films via a Plasma-Enhanced Quasi-ALD/ALE Supercycle SangTae Park ¹ , HyunJin Lim ¹ , YehBeen Im ¹ , Young Seo Na ² , SeungChae Lee ¹ , KangBaek Seo ² , DongUk Kim ² , KangHyeok Lee ² , and Changhwan Choi ^{1,2} ¹ Division of Materials Science and Engineering, Hanyang University, ² Department of Semiconductor Engineering, Hanyang University
WP-034	유기가스를 이용한 몰리브덴 박막의 플라즈마 강화 원자층 식각 정호진 ^{1,2} , 양홍주 ^{1,2} , 원대한 ^{1,2} , 송하린 ^{1,2} , 정지원 ^{1,2} , 백인환 ^{1,2} ¹ Department of Chemical Engineering, Inha University, ² Program in



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	Semiconductor Convergence, Inha University
WP-035	<p>Silicon Oxide Etch Rate Model with Optical Emission Spectroscopy and VI-Probe</p> <p>Eunchong Park¹, Minseong Kim², Sanghee Han³, Jaehyeon Kim³, and Heeyeop Chae^{2,3}</p> <p>¹Department of Nano Science and Technology, SKKU Advanced Institute of Nanotechnology, Sungkyunkwan University, ²Department of Semiconductor Convergence Engineering, Sungkyunkwan University, ³School of Chemical Engineering, Sungkyunkwan University</p>

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[WP] 포스터세션

V. Quantum Technology 분과

WP-371	<div>Design and Simulation of a 2-Qubit Superconducting Quantum Processor</div> <div>Jiwon Seok, Seung-Young Seo, and Jae-Yoon Sim</div> <div>Department of Electronic and Electrical Engineering, POSTECH</div>
WP-372	<div>Anharmonic GHz Phonon Modes in Josephson Junction Tunnel Barriers: A First-Principles Study</div> <div>Yosep Park¹ and Yeonghun Lee^{1,2}</div> <div>¹Department of Intelligent Semiconductor Engineering, Incheon National University, ²Department of Electronics Engineering, Incheon National University</div>
WP-373	<div>Site-Controlled Quantum Dot Embedding in GaAs Nanowires on Silicon</div> <div>Illia Tikhonov^{1,2}, Sung-Yul L. Park¹, Ga Hyun Cho^{1,3}, and Jindong Song^{1,2}</div> <div>¹KIST, ²University of Science and Technology, ³Hanyang University</div>
WP-374	<div>Design and Optimization of 493 nm Inversely Tapered Edge Couplers for Low-Loss Coupling in Ba⁺ Ion-Trap Quantum Computing Platforms</div> <div>Seung-Gun Kim¹, Jaewoo Kim¹, Chiyeon Kim², Changsoon Kim³, Taehyun Kim², Donghwan Ahn¹, and Youngmin Kim¹</div> <div>¹School of Materials Science and Engineering, Kookmin University, ²Department of Computer Science and Engineering, Seoul National University, ³Department of Intelligence and Information, Seoul National University</div>
WP-375	<div>Scalable Ground-State Cooling of 40Ca⁺ Ion Chains via Electromagnetically Induced Transparency and Observation of Mode Mixing</div> <div>Kim Keumhyun, Lee Hyegoo, SHIN Yongha, HAN Sangsoo, CHO Junhee, KIM Myunghun, GWON Sehyeon, Moon Youngil, and LEE Moonjoo</div> <div>Electrical Engineering, POSTECH</div>



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WP-376	Hybrid Quantum-Classical DMFT for Hubbard Model Juyeon Kim and Yeonghun Lee Department of Electronics Engineering, Incheon National University
WP-377	Quasiperiodic Dynamics of a Trapped-Ion Mechanical Oscillator Myunghun Kim, Sehyeon Gwon, Sangsoo Han, Junhee Cho, Keumhyun Kim, Hyegoo Lee, Yongha Shin, Youngil Moon, Kiyanooush Goudarzi, and Moonjoo Lee Department of Electrical Engineering, POSTECH
WP-378	양자점 단일광자 결합을 위한 MgO 도핑 TFLN 기반 광대역·편광 비의존 모드 사이즈 컨버터 김보성, 김구환, 김홍석, 문기원, 주정진, 박재규 한국전자통신연구원 양자기술연구본부 양자센서연구실
WP-379	Experimental Implementation of Tunable Spin-Spin Couplings between 40Ca^+ Ions LEE Hyegoo, KIM Keumhyun, SHIN Yongha, HAN Sangsoo, CHO Junhee, MOON Young Il, KIM Myunghun, GWON Sehyeon, and LEE Moonjoo Electrical Engineering Department, POSTECH
WP-380	Anti-Reflection Coating for Integrated-Photonic-Circuit-Based Ba^+ Trapped-Ion Chips Uihwan Jeong ^{1,2,3} , Chiyeon Kim ^{1,2,3} , Suhan Kim ^{1,2,3} , Kwangyeul Choi ^{1,2,3} , Seungwoo Yu ^{1,2,3} , Changsoon Kim ⁴ , and Taehyun Kim ^{1,2,3} ¹ Department of Computer Science and Engineering, Seoul National University, ² Automation and System Research Institute, Seoul National University, ³ Inter-university Semiconductor Research Center, Seoul National University, ⁴ Department of Intelligence and Information, Seoul National University



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[WP] 포스터세션

A. Interconnect & Package 분과

WP-381	<p>포트 모델링 기법을 사용한 S-파라미터 시뮬레이션-측정 상관성 개선</p> <p>표승수¹, 김문정¹, 진병규²</p> <p>¹국립공주대학교 전기전자제어공학과, ²보스반도체</p>
WP-382	<p>소재 및 공정 기반 모델링을 사용한 S-파라미터 정합성 향상</p> <p>이현아¹, 박혜준², 김문정¹</p> <p>¹국립공주대학교 전기전자제어공학과, ²아이원</p>
WP-383	<p>PCB 전송선로의 임피던스 불연속 구간에 대한 전기적 특성 분석</p> <p>정준호¹, 진병규², 김문정¹</p> <p>¹국립공주대학교 전기전자제어공학과, ²보스반도체</p>